

MOS Integrated Circuit $\mu PD720122$

USB2.0 Generic Device Controller



The μ PD720122 is USB2.0 Generic Device Controller, which combines the NEC Electronics USB2.0 PHY and Endpoint Controller. The Controller has certified by USB Implementers Forum. End-point Controller has banked two Bulk Endpoint and one Interrupt End-point, and selectable three general CPU bus-types, suitable for designing various USB device. The controller has the external local bus, that enables to perform high speed data transferring when CPU is accessing to the controller. These IP Blocks in the controller are based completely on an NEC Electronics ASIC core, so μ PD720122 is suitable to design for the prototype system that are intended to design ASIC in the future.

Detailed function descriptions are provided in the following user's manual. Be sure to read the manual before designing. μ PD720122 User's Manual: S15829E

FEATURES

- Complaint with USB2.0 specification (Maximum data transferring rate: 480 Mbps)
- USB2.0 certified (TestID=40000822)
- High(480Mbps) / Full(12Mbps)- Speed support and switch automatically
- · Easy to design NEC Electronics ASIC
- Generic USB2.0 Device Controller
- Two Bulk End-points and One Interrupt End-point
- Performed Data Local Bus independent from CPU bus.
 (Maximum Data Transferring rate: 21 MBps with DMA mode)
- Selectable three CPU Bus Interface

ORDERING INFORMATION

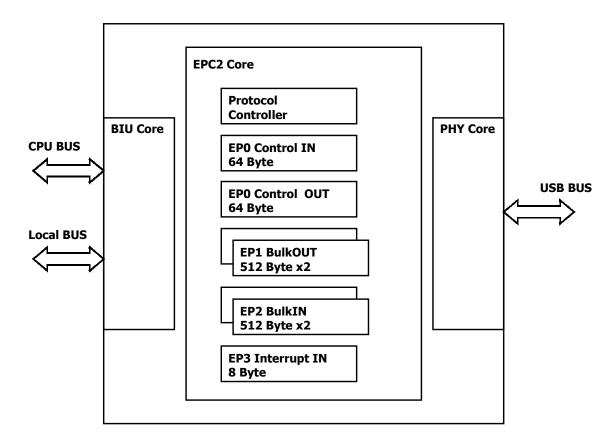
Part Number	Package
μ PD720122GC-9EU	100-pin plastic TQFP (Fine pitch) (14 \times 14)
μPD720122F1-DN2	109-pin plastic FBGA (11 × 11)

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Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.



BLOCK DIAGRAM



PHY Core : USB2.0 transceiver with serial interface engine

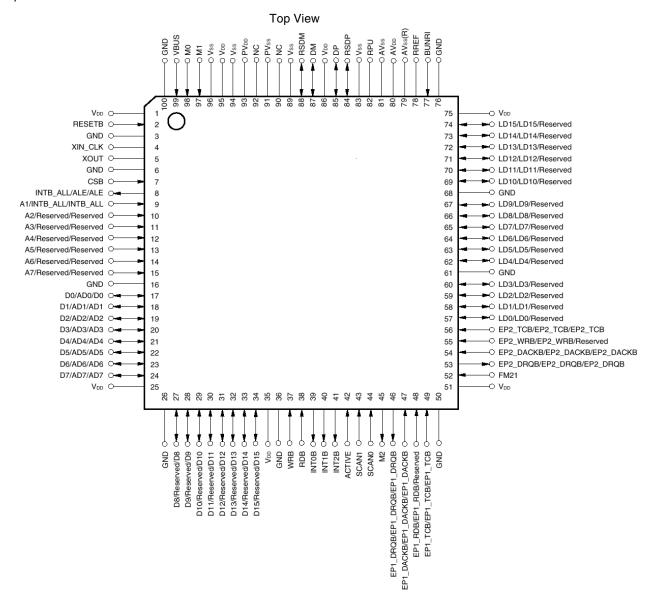
EPC2 Core : Endpoint controller
BIU Core : Bus Interface Unit



PIN CONFIGURATION

• 100-pin plastic TQFP (Fine pitch) (14 × 14)

μ PD720122GC-9EU



Remark The function of the pin is shown with Function 1/Function 2/Function 3 from the left.



 μ PD720122GC-9EU (1/2)

	2012240-320						(1/2)
Pin	Pin Name	Pin Name	Pin Name	Pin	Pin Name	Pin Name	Pin Name
No.	Function1	Function2	Function3	No.	Function1	Function2	Function3
1	V_{DD}	V _{DD}	V _{DD}	26	GND	GND	GND
2	RESETB	RESETB	RESETB	27	D8	Reserved	D8
3	GND	GND	GND	28	D9	Reserved	D9
4	XIN_CLK	XIN_CLK	XIN_CLK	29	D10	Reserved	D10
5	XOUT	XOUT	XOUT	30	D11	Reserved	D11
6	GND	GND	GND	31	D12	Reserved	D12
7	CSB	CSB	CSB	32	D13	Reserved	D13
8	INTB_ALL	ALE	ALE	33	D14	Reserved	D14
9	A1	INTB_ALL	INTB_ALL	34	D15	Reserved	D15
10	A2	Reserved	Reserved	35	V _{DD}	V _{DD}	V _{DD}
11	А3	Reserved	Reserved	36	GND	GND	GND
12	A4	Reserved	Reserved	37	WRB	WRB	WRB
13	A 5	Reserved	Reserved	38	RDB	RDB	RDB
14	A6	Reserved	Reserved	39	INT0B	INT0B	INT0B
15	A7	Reserved	Reserved	40	INT1B	INT1B	INT1B
16	GND	GND	GND	41	INT2B	INT2B	INT2B
17	D0	AD0	D0	42	ACTIVE	ACTIVE	ACTIVE
18	D1	AD1	AD1	43	SCAN1	SCAN1	SCAN1
19	D2	AD2	AD2	44	SCAN0	SCAN0	SCAN0
20	D3	AD3	AD3	45	M2	M2	M2
21	D4	AD4	AD4	46	EP1_DRQB	EP1_DRQB	EP1_DRQB
22	D5	AD5	AD5	47	EP1_DACKB	EP1_DACKB	EP1_DACKB
23	D6	AD6	AD6	48	EP1_RDB	EP1_RDB	Reserved
24	D7	AD7	AD7	49	EP1_TCB	EP1_TCB	EP1_TCB
25	V_{DD}	V_{DD}	V_{DD}	50	GND	GND	GND



 μ PD720122GC-9EU (2/2)

Pin	Pin Name	Pin Name	Pin Name	Pin	Pin Name	Pin Name	Pin Name
No.	Fucntion1	Function2	Function3	No.	Fucntion1	Function2	Function3
51	V _{DD}	V _{DD}	V _{DD}	76	GND	GND	GND
52	FM21	FM21	FM21	77	BUNRI	BUNRI	BUNRI
53	EP2_DRQB	EP2_DRQB	EP2_DRQB	78	RREF	RREF	RREF
54	EP2_DACKB	EP2_DACKB	EP2_DACKB	79	AVss(R)	AVss(R)	AVss(R)
55	EP2_WRB	EP2_WRB	Reserved	80	AV _{DD}	AV _{DD}	AV _{DD}
56	EP2_TCB	EP2_TCB	EP2_TCB	81	AVss	AVss	AVss
57	LD0	LD0	Reserved	82	RPU	RPU	RPU
58	LD1	LD1	Reserved	83	Vss	Vss	Vss
59	LD2	LD2	Reserved	84	RSDP	RSDP	RSDP
60	LD3	LD3	Reserved	85	DP	DP	DP
61	GND	GND	GND	86	V _{DD}	V _{DD}	V _{DD}
62	LD4	LD4	Reserved	87	DM	DM	DM
63	LD5	LD5	Reserved	88	RSDM	RSDM	RSDM
64	LD6	LD6	Reserved	89	Vss	Vss	Vss
65	LD7	LD7	Reserved	90	NC	NC	NC
66	LD8	LD8	Reserved	91	PVss	PVss	PVss
67	LD9	LD9	Reserved	92	NC	NC	NC
68	GND	GND	GND	93	PV _{DD}	PV _{DD}	PV _{DD}
69	LD10	LD10	Reserved	94	Vss	Vss	Vss
70	LD11	LD11	Reserved	95	V _{DD}	V _{DD}	V _{DD}
71	LD12	LD12	Reserved	96	Vss	Vss	Vss
72	LD13	LD13	Reserved	97	M1	M1	M1
73	LD14	LD14	Reserved	98	MO	MO	MO
74	LD15	LD15	Reserved	99	VBUS	VBUS	VBUS
75	V _{DD}	V _{DD}	V _{DD}	100	GND	GND	GND

Remark AVss (R) should be used to connect RREF through 1 % precision reference resistor of 9.1 k Ω .



• 109-pin plastic FBGA (11 × 11)

 μ PD720122F1-DN2

Bottom View

												_
23 NC	24 BUNRI	25 AVss(R)	26 AVss	27 RSDP	28 V _{DD}	29 NC	30 NC	31 V _{DD}	32 M1	33 VBUS	34 NC	12
22 LD15	63 NC	64 RREF	65 AV _{DD}	66 GND	67 RSDM	68 PVss	69 GND	70 GND	71 M0	72 NC	35 RESETB	11
21 LD13	62 LD14	95 GND	96 RPU	97 DP	98 GND	99 DM	100 PV _{DD}	101 V _{DD}	102 GND	73 GND	36 XIN_CLK	10
20 LD11	61 LD12	94 V _{DD}							103 CSB	74 XOUT	37 GND	9
19 LD9	60 LD10	93 GND							104 A2	75 INTB_ALL	38 A1	8
18 LD7	59 LD8	92 LD4							105 A6	76 A 5	39 A3	7
17 GND	58 LD5	91 LD6							106 A4	77 GND	40 A7	6
16 LD2	57 LD1	90 LD3							107 D1	78 D2	41 D0	5
15 EP2_TCB	56 EP2_WRB	89 LD0						109 GND	108 V _{DD}	79 D4	42 D3	4
14 EP2_DACKB	55 EP2_DRQB	88 GND	87 V _{DD}	86 SCAN1	85 WRB	84 INT0B	83 V _{DD}	82 D13	81 GND	80 D6	43 D5	3
13 FM21	54 NC	53 EP1_RDB	52 EP1_DRQB	51 SCAN0	50 INT2B	49 RDB	48 D14	47 D11	46 D9	45 NC	44 D7	2
12 NC	11 EP1_TCB	10 EP1_DACKB	9 M2	8 ACTIVE	7 INT1B	6 GND	5 D15	4 D12	3 D10	2 D8	1 NC	1
М	L	K	J	н	G	F	Е	D	С	В	Α	

Remarks The pin name is showing it with Function1.

As for the pin name of Function2 and Function3, please refer to the table of the next page.



 μ PD720122F1-DN2 (1/2)

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Pin	Pin Name	Pin Name	Pin Name	Pin	Pin Name	Pin Name	Pin Name
No.	Function1	Function2	Function3	No.	Function1	Function2	Function3
1	NC	NC	NC	26	AV _{ss}	AV_{ss}	AV _{ss}
2	D8	Reserved	D8	27	RSDP	RSDP	RSDP
3	D10	Reserved	D10	28	V _{DD}	V _{DD}	V _{DD}
4	D12	Reserved	D12	29	NC	NC	NC
5	D15	Reserved	D15	30	NC	NC	NC
6	GND	GND	GND	31	V _{DD}	V _{DD}	$V_{\scriptscriptstyle DD}$
7	INT1B	INT1B	INT1B	32	M1	M1	M1
8	ACTIVE	ACTIVE	ACTIVE	33	VBUS	VBUS	VBUS
9	M2	M2	M2	34	NC	NC	NC
10	EP1_DACKB	EP1_DACKB	EP1_DACKB	35	RESETB	RESETB	RESETB
11	EP1_TCB	EP1_TCB	EP1_TCB	36	XIN_CLK	XIN_CLK	XIN_CLK
12	NC	NC	NC	37	GND	GND	GND
13	FM21	FM21	FM21	38	A1	INTB_ALL	INTB_ALL
14	EP2_DACKB	EP2_DACKB	EP2_DACKB	39	А3	Reserved	Reserved
15	EP2_TCB	EP2_TCB	EP2_TCB	40	A7	Reserved	Reserved
16	LD2	LD2	Reserved	41	D0	AD0	D0
17	GND	GND	GND	42	D3	AD3	AD3
18	LD7	LD7	Reserved	43	D5	AD5	AD5
19	LD9	LD9	Reserved	44	D7	AD7	AD7
20	LD11	LD11	Reserved	45	NC	NC	NC
21	LD13	LD13	Reserved	46	D9	Reserved	D9
22	LD15	LD15	Reserved	47	D11	Reserved	D11
23	NC	NC	NC	48	D14	Reserved	D14
24	BUNRI	BUNRI	BUNRI	49	RDB	RDB	RDB
25	AV _{ss} (R)	AV _{ss} (R)	AV _{ss} (R)	50	INT2B	INT2B	INT2B
25	AV _{ss} (R)	AV _{ss} (R)	AV _{ss} (R)	50	INT2B	INT2B	INT2B

Remark AVss (R) should be used to connect RREF through 1 % precision reference resistor of 9.1 k Ω .



 μ PD720122F1-DN2 (2/2)

Pin Pin Name Pin Seserved Pin Name Pin Seserved Pin Name Pin Seserved Pin Name Pin Seserved Din Name Pin Name Pin Seserved Pin Name Pin Name Pin Seserved Din Name Pin Din Name 4 No No <th>μ</th> <th>D120122F1-DN</th> <th>_</th> <th></th> <th></th> <th></th> <th></th> <th>(2/2)</th>	μ	D120122F1-DN	_					(2/2)
51 SCANO SCANO SCANO 81 GND GND 52 EP1_DROB EP1_DROB EP1_DROB EP1_DROB EP1_DROB B2 D13 Reserved D13 53 EP1_RDB EP1_RDB Reserved 83 V ₁₀₀ V ₁₀₀ V ₁₀₀ 54 NC NC NC 84 INTOB INTOB INTOB 55 EP2_DROB EP2_DROB EP2_DROB B8 WRB WRB WRB 56 EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 87 V ₂₀ V ₂₀ V ₂₀ 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LB Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD	Pin	Pin Name	Pin Name	Pin Name	Pin	Pin Name	Pin Name	Pin Name
52 EP1_DROB EP1_DROB EP1_DROB 82 D13 Reserved D13 53 EP1_RDB EP1_RDB Reserved 83 V ₁₀ V ₀₀ V ₂₀ 54 NC NC NC 84 INTOB INTOB INTOB 55 EP2_DRQB EP2_DRQB EP2_DRQB 85 WRB WRB WRB 56 EP2_WRB EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 88 GND GND GND 58 LD5 LD5 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 LD6 Reserved 61 LD14 Reserved 92 LD4 LD4 Reserved 62 LD14 RESER	No.	Function1	Function2	Function3	No.	Function1	Function2	Function3
53 EP1_RDB EP1_RDB Reserved 83 V ₁₀ V ₂₀ V ₂₀ 54 NC NC NC 84 INT0B INT0B INT0B 55 EP2_DRQB EP2_DRQB EP2_DRQB 85 WRB WRB WRB 56 EP2_WRB EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 87 V ₂₀ V ₅₀ V ₅₀ 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 LD6 Reserved 61 LD14 Reserved 91 LD6 LD6 LD6 Reserved Reserved 92 LD4	51	SCAN0	SCAN0	SCAN0	81	GND	GND	GND
54 NC NC NC 84 INTOB INTOB INTOB 55 EP2_DRQB EP2_DRQB EP2_DRQB 85 WRB WRB WRB 56 EP2_WRB EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 87 V ₅₀ V ₅₀ V ₅₀ 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF	52	EP1_DRQB	EP1_DRQB	EP1_DRQB	82	D13	Reserved	D13
55 EP2_DRQB EP2_DRQB EP2_DRQB 85 WRB WRB WRB 56 EP2_WRB EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 87 V ₀₀ V ₀₀ V ₀₀ 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V ₀₀ V ₀₀ V ₀₀ 65 AV ₀₀ AV ₀₀ <	53	EP1_RDB	EP1_RDB	Reserved	83	V _{DD}	V _{DD}	V _{DD}
56 EP2_WRB EP2_WRB Reserved 86 SCAN1 SCAN1 SCAN1 57 LD1 LD1 Reserved 87 V _{so} V _{so} V _{so} 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V _{so} V _{so} V _{so} 65 AV _{so} AV _{so} AV _{so} 95 GND GND GND 66 GND GND GND	54	NC	NC	NC	84	INT0B	INT0B	INT0B
57 LD1 LD1 Reserved 87 V _{so} V _{so} V _{so} 58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NS 93 GND GND GND 64 RREF RREF RREF 94 V _{so} V _{so} V _{so} 65 AV _{so} AV _{so} 95 GND GND GND 66 GND GND GND GND GND GND 67 RSDM RSDM RSDM RSDM RSDM	55	EP2_DRQB	EP2_DRQB	EP2_DRQB	85	WRB	WRB	WRB
58 LD5 LD5 Reserved 88 GND GND GND 59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V _{co} V _{co} V _{co} 65 AV _{co} AV _{co} 95 GND GND GND GND 66 GND GND GND 96 RPU RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP DP 68 PV _{ss} PV _{ss}	56	EP2_WRB	EP2_WRB	Reserved	86	SCAN1	SCAN1	SCAN1
59 LD8 LD8 Reserved 89 LD0 LD0 Reserved 60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V ₀₀ V ₀₀ V ₀₀ 65 AV ₀₀ AV ₀₀ AV ₀₀ 95 GND GND GND 66 GND GND GND GND GND GND GND 67 RSDM RSDM RSDM 97 DP DP DP DP 68 PV ₈₈ PV ₈₈ PV ₈₈ 98 GND GND GND GND 69 GND	57	LD1	LD1	Reserved	87	V _{DD}	V _{DD}	V _{DD}
60 LD10 LD10 Reserved 90 LD3 LD3 Reserved 61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V ₀₀ V ₀₀ V ₀₀ 65 AV ₀₀ AV ₀₀ 95 GND GND GND 66 GND GND GND GND GND RPU RPU RPU 67 RSDM RSDM RSDM 97 DP	58	LD5	LD5	Reserved	88	GND	GND	GND
61 LD12 LD12 Reserved 91 LD6 LD6 Reserved 62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V ₅₀ V ₅₀ V ₅₀ 65 AV ₅₀ AV ₅₀ 95 GND GND GND 66 GND GND GND 96 RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP DP 68 PV ₅₈ PV ₅₈ 98 GND DM	59	LD8	LD8	Reserved	89	LD0	LD0	Reserved
62 LD14 LD14 Reserved 92 LD4 LD4 Reserved 63 NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V ₀₀ V ₀₀ V ₀₀ 65 AV ₀₀ AV ₀₀ 95 GND GND GND 66 GND GND GND 96 RPU RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP DP 68 PV _{ss} PV _{ss} 98 GND DM	60	LD10	LD10	Reserved	90	LD3	LD3	Reserved
63 NC NC NC 93 GND GND GND 64 RREF RREF RREF 94 V _{DD} V _{DD} V _{DD} 65 AV _{DD} AV _{DD} 95 GND GND GND 66 GND GND GND 96 RPU RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP DP 68 PV _{SS} PV _{SS} 98 GND GND GND GND 69 GND GND GND DM DM DM DM 70 GND GND GND 100 PV _{DD} PV _{DD} PV _{DD} 71 MO MO MO MO 101 V _{DD} PV _{DD} PV _{DD} 72 NC NC NC NC 102 GND GND GND GND 73 GND GND G	61	LD12	LD12	Reserved	91	LD6	LD6	Reserved
64 RREF RREF RREF 94 V _{DD} V _{DD} V _{DD} 65 AV _{DD} AV _{DD} 95 GND GND GND 66 GND GND GND 96 RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP 68 PV _{SS} PV _{SS} 98 GND GND GND 69 GND GND GND DM DM DM 70 GND GND GND PV _{DD} PV _{DD} PV _{DD} 71 M0 M0 M0 101 V _{DD} V _{DD} V _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_AL	62	LD14	LD14	Reserved	92	LD4	LD4	Reserved
65 AV _{DD} AV _{DD} 95 GND GND GND 66 GND GND GND 96 RPU RPU RPU 67 RSDM RSDM RSDM 97 DP DP DP 68 PV _{SS} PV _{SS} 98 GND GND GND 69 GND GND GND DM DM DM 70 GND GND GND PV _{DD} PV _{DD} PV _{DD} 71 M0 M0 M0 101 V _{DD} PV _{DD} PV _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND GND GND GND 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5	63	NC	NC	NC	93	GND	GND	GND
66 GND GND GND 96 RPU RPU RPU RPU 67 RSDM RSDM 97 DP DP DP DP 68 PV _{ss} PV _{ss} 98 GND GND GND GND GND GND GND GND DM DM <t< td=""><td>64</td><td>RREF</td><td>RREF</td><td>RREF</td><td>94</td><td>V_{DD}</td><td>V_{DD}</td><td>V_{DD}</td></t<>	64	RREF	RREF	RREF	94	V _{DD}	V _{DD}	V _{DD}
67 RSDM RSDM PSDM 97 DP DP DP 68 PVss PVss 98 GND GND GND 69 GND GND GND 99 DM DM DM 70 GND GND GND 100 PVoD PVoD PVoD 71 M0 M0 M0 101 VoD VoD VoD VoD 72 NC NC NC 102 GND GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D	65	AV _{DD}	AV _{DD}	AV _{DD}	95	GND	GND	GND
68 PV _{ss} PV _{ss} 98 GND GND GND 69 GND GND GND 99 DM DM DM 70 GND GND GND 100 PV _{DD} PV _{DD} PV _{DD} 71 M0 M0 M0 101 V _{DD} V _{DD} V _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD}	66	GND	GND	GND	96	RPU	RPU	RPU
69 GND GND 99 DM DM DM 70 GND GND 100 PV _{DD} PV _{DD} PV _{DD} 71 M0 M0 M0 101 V _{DD} V _{DD} V _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND <td>67</td> <td>RSDM</td> <td>RSDM</td> <td>RSDM</td> <td>97</td> <td>DP</td> <td>DP</td> <td>DP</td>	67	RSDM	RSDM	RSDM	97	DP	DP	DP
70 GND GND GND 100 PV _{DD} PV _{DD} PV _{DD} 71 M0 M0 M0 101 V _{DD} V _{DD} V _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	68	PV _{ss}	PV_{ss}	PV_{ss}	98	GND	GND	GND
71 M0 M0 M0 101 V _{DD} V _{DD} V _{DD} 72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	69	GND	GND	GND	99	DM	DM	DM
72 NC NC NC 102 GND GND GND 73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	70	GND	GND	GND	100	$PV_{\mathtt{DD}}$	$PV_{\mathtt{DD}}$	PV_{DD}
73 GND GND GND 103 CSB CSB CSB 74 XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	71	MO	MO	MO	101	$V_{\scriptscriptstyle DD}$	V _{DD}	V _{DD}
74 XOUT XOUT 104 A2 Reserved Reserved 75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	72	NC	NC	NC	102	GND	GND	GND
75 INTB_ALL ALE ALE 105 A6 Reserved Reserved 76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	73	GND	GND	GND	103	CSB	CSB	CSB
76 A5 Reserved Reserved 106 A4 Reserved Reserved 77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	74	XOUT	XOUT	XOUT	104	A2	Reserved	Reserved
77 GND GND GND 107 D1 AD1 AD1 78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	75	INTB_ALL	ALE	ALE	105	A6	Reserved	Reserved
78 D2 AD2 AD2 108 V _{DD} V _{DD} V _{DD} 79 D4 AD4 AD4 109 GND GND GND	76	A 5	Reserved	Reserved	106	A4	Reserved	Reserved
79 D4 AD4 AD4 109 GND GND GND	77	GND	GND	GND	107	D1	AD1	AD1
79 D4 AD4 AD4 109 GND GND GND	78	D2	AD2	AD2	108	V _{DD}	V _{DD}	V _{DD}
go De ADe ADe	79	D4	AD4	AD4	109		GND	GND
	80	D6	AD6	AD6	-	-	-	-



1. PIN INFORMATION

(1/2)

Pin Name	I/O	Buffer Type	Active Level	Function (1/2
RESETB	I	5 V tolerant Input Schmitt	Low	Asynchronous reset signaling
XIN_CLK	I	3.3 V Input		System clock input or oscillator In
XOUT	0	3.3 V Output		Oscillator out
CSB	I	5 V tolerant Input	Low	Chip select signal
INTB_ALL	0	5 V tolerant Output	Low	Interrupt request signal
ALE	I	5 V tolerant Input	High	Address strobe signal (Function2/3)
A(7:1)	ı	5 V tolerant Input		Address input (Function1)
D(15:0)	I/O	5 V tolerant I/O		Data bus (I/O) (Function1)
AD(7:0)	I/O	5 V tolerant I/O		Address/data multiplexed bus (I/O) (Function2)
D0	I/O	5 V tolerant I/O		Data bus (I/O) (Function3)
AD(7:1)	I/O	5 V tolerant I/O		Address/data multiplexed bus (I/O) (Function3)
D(15:8)	I/O	5 V tolerant I/O		Data bus (I/O) (Function3)
WRB	I	5 V tolerant Input	Low	Write command input
RDB	I	5 V tolerant Input	Low	Read command input
INT0B	0	5 V tolerant Output	Low	Interrupt request (INT Status 0)
INT1B	0	5 V tolerant Output	Low	Interrupt request (INT Status 1)
INT2B	0	5 V tolerant Output	Low	Interrupt request (INT Status 2)
ACTIVE	I	5 V tolerant Input		DMA-related pins active level select(Function2/3)
SCAN(1:0)	I	3.3 V Input 50 kΩ Pull Down		Chip test pin.
M2	0	5 V tolerant Output		Status output pin
EP1_DRQB	0	5 V tolerant Output	Low	DMA transfer request output pin of EP1
EP1_DACKB	ı	5 V tolerant Input	Low	DMA transfer enable input pin of EP1
EP1_RDB	ı	5 V tolerant Input	Low	DMA Read command input pin of EP1
EP1_TCB	ı	5 V tolerant Input	Low	DMA terminal count input pin of EP1
FM21	ı	3.3 V Input		NEC Electronics test pin
EP2_DRQB	0	5 V tolerant Output	Low	DMA transfer request output pin of EP2
EP2_DACKB	ı	5 V tolerant Input	Low	DMA transfer enable input pin of EP2
EP2_WRB	ı	5 V tolerant Input	Low	DMA Write command input pin of EP2
EP2_TCB	ı	5 V tolerant Input	Low	DMA terminal count input pin of EP2
LD(15:0)	I/O	5 V tolerant I/O		Data bus (I/O) pin for external local bus
BUNRI	ı	5V torelant Input		NEC Electronics test pin
RREF	Α	Analog		Reference resistor
RPU	Α	USB pull-up control		USB's 1.5 kΩ pull-up resistor control
RSDP	0	USB full speed D+ O		USB's full speed D+ signal
DP	I/O	USB high speed D+ I/O		USB's high speed D+ signal
DM	I/O	USB high speed D- I/O		USB's high speed D- signal

(2/2)

Pin Name	I/O	Buffer Type	Active Level	Function
RSDM	0	USB full speed D- O		USB's full speed D- signal
M(1:0)	I	5 V tolerant Input		Function mode setting
VBUS	1	5 V tolerant Input Note		VBUS monitoring
AVDD, PVDD				3.3 V _{DD} for Analog circuit
V _{DD}				3.3 V _{DD}
AVss, PVss				Vss for Analog circuit
Vss, GND				Vss
NC				Not connect
Reserved				Not used

Note

VBUS pin may be used to monitor for VBUS line even if V_{DD} , AV_{DD} , and PV_{DD} are shut off. System must ensure that the input voltage level for VBUS pin is less than 3.0 V due to the absolute maximum rating is not exceeded.

Remark "5 V tolerant" means that the buffer is 3.3 V buffer with 5 V tolerant circuit.

The operation mode of the BIU can be set by external pins, as shown below. Fix external pins (M1 and M0) when

using them.

using P	Pin BIU Operation Mode		Outline
M1	MO		
0	0	16-bit mode (Function 1)	A 16-bit CPU bus and an external local bus dedicated to data transfer for bulk IN/OUT can be used in this mode. The internal register length is 16 bits.
0	1	8-bit mode (Function 2)	Multiplexed bus mode of 8-bit address bus and 8-bit data bus. The register length is 8 bits only in this mode (registers can only be accessed in byte units). Therefore, the address space in this mode differs from that in the other modes. The active levels of some external local bus control pins can be changed by the Active pin.
1	0	16-bit mix mode (Function 3)	Multiplexed bus mode of 8-bit address bus and 16-bit data bus. The internal register length is 16 bits. The active levels of some external local bus control pins can be changed by the Active pin.
1	1	Setting prohibited (Function 4)	Setting prohibited



2. ELECTRICAL SPECIFICATIONS

2.1 Buffer List

• 3.3 V oscillator interface

XIN,XOUT

• 3.3 V input buffer

FM21,SCAN(1:0)

• 5V torelant input buffer

RESETB,CSB,A(7:0),WRB,RDB,ACTIVE,EP1_DACKB,EP1_RDB,EP1_TCB,EP2_DACKB,EP2_WRB, EP2_TCB,BUNRI,M0,M1,VBUS,ALE

• 5V torelant output buffer

INTB_ALL,INT0B,INT1B,INT2B,M2,EP1_DRQB,EP2_DRQB

• 5V torelant I/O buffer

D(15:0),LD(15:0),AD(7:0),D0,AD(7:1),D(15:8)

• USB interface

DP,DM,RSDP,RSDM,RREF,RPU

2.2 Terminology

Terms Used in Absolute Maximum Ratings

Parameter	Symbol	Meaning
Power supply voltage	V _{DD}	Indicates voltage range within which damage or reduced reliability will not result when power is applied to a VDD pin.
Input voltage	Vı	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an input pin.
Output voltage	Vo	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an output pin.
Output current	lo	Indicates absolute tolerance value for DC current to prevent damage or reduced reliability when a current flows out of or into an output pin.
Operating temperature	TA	Indicates the ambient temperature range for normal logic operations.
Storage temperature	Tstg	Indicates the element temperature range within which damage or reduced reliability will not result while no voltage or current are applied to the device.



Terms Used in Recommended Operating Range

Parameter	Symbol	Meaning
Power supply voltage	V _{DD}	Indicates the voltage range for normal logic operations occur when Vss = 0 V.
High-level input voltage	Vін	Indicates the voltage, which is applied to the input pins of the device, is the voltage indicates that the high level states for normal operation of the input buffer. * If a voltage that is equal to or greater than the "Min." value is applied, the input voltage is guaranteed as high level voltage.
Low-level input voltage	VIL	Indicates the voltage, which is applied to the input pins of the device, is the voltage indicates that the low level states for normal operation of the input buffer. * If a voltage that is equal to or lesser than the "Max." value is applied, the input voltage is guaranteed as low level voltage.
Hysteresys voltage	VH	Indicates the differential between the positive trigger voltage and the negative trigger voltage.
Input rise time	tri	Indicates allowable input rise time to input pins. Input rise time is transition time from $0.1 \times V_{DD}$ to $0.9 \times V_{DD}$.
Input fall time	tri	Indicates allowable input fall time to input pins. Input fall time is transition time from $0.9 \times V_{DD}$ to $0.1 \times V_{DD}$.

Terms Used in DC Characteristics

Parameter	Symbol	Meaning
Off-state output leakage current	loz	Indicates the current that flows from the power supply pins when the rated power supply voltage is applied when a 3-state output has high impedance.
Output short circuit current	los	Indicates the current that flows when the output pin is shorted (to GND pins) when output is at high-level.
Input leakage current	lı	Indicates the current that flows when the input voltage is supplied to the input pin.
Low-level output current	Іоц	Indicates the current that flows to the output pins when the rated low-level output voltage is being applied.
High-level output current	Іон	Indicates the current that flows from the output pins when the rated high-level output voltage is being applied.



2.3 Absolute Maximum Ratings

	Parameter	Symbol	Conditions	Ratings	Unit
Voltage		V _{DD}		-0.5 to +4.6	V
I/O volta	age	Vı/Vo			
	Note 1		V _I /V _O < V _{DD} +3.0 V	-0.5 to +6.6	V
	Note 2		V _I /V _O < V _{DD} +0.3 V	-0.5 to +4.6	V
Output o	current	lo			
	Note 3		IoL = 6 mA	6	mA
Operatir	ng ambient temperature	TA		0 to +70	°C
Storage	temperature	Tstg		-65 to +150	°C

Notes 1. 5 V torelant input buffer, output buffer, I/O buffer

- 2. 3.3 V input buffer, 3.3 V oscillator interface
- **3.** 5 V torelant output buffer, I/O buffer(OUT)

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

2.4 Recommended Operating Range

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Power supply voltage	V _{DD}	3.3 V Power	3.0	3.3	3.6	V
Negative trigger voltage	Vn		0.6		1.8	V
Positive trigger voltage	VP		1.2		2.4	V
Hysteresis voltage	Vн		0.3		1.5	V
Input voltage, low	VIL		0		0.8	V
Input voltage, high	Vін	3.3 V input buffer	2.0		V _{DD}	V
		5V torelant input buffer, I/O buffer	2.0		5.5	٧
Rise/fall time	tr/tf		0		200	ns



2.5 DC Characteristics

The DC characteristics are classified into those of the USB interface and those of the BIU block.

2.5.1 DC characteristics of USB interface

Parameter	Symbol	Conditions	Min.	Max.	Unit
Serial resistor between DP (DM) and RSDP (RSDM)	Rs		35.64	36.36	Ω
Driver output resistance (also serves as high-speed termination)	Zhsdrv	Includes Rs resistor	40.5	49.5	Ω
Bus pull-up resistor on upstream facing port	Rpu		1.425	1.575	Ω
Termination voltage for upstream facing port pull-up (full-speed)	VTERM		3.0	3.6	٧
Input levels for full-speed:					
High-level input voltage (driven)	ViH		2.0		V
High-level input voltage (floating)	VIHZ		2.7	3.6	
Low-level input voltage	VIL			0.8	V
Differential input sensitivity	V _{DI}	(D+) - (D-)	0.2		V
Differential common mode range	Vсм	Includes Vol range	0.8	2.5	V
Output levels for full-speed:					
High-level output voltage	Vон	R _L of 14.25 kΩ to Vss	2.8	3.6	V
Low-level output voltage	Vol	R∟ of 1.425 kΩ to 3.6 V	0.0	0.3	V
SE1	Vose1		0.8		V
Output signal crossover voltage	Vcrs		1.3	2.0	V
Input levels for high-speed:					
High-speed squelch detection threshold (differential signal amplitude)	VHSSQ		100	150	mV
High-speed disconnect detection threshold (differential signal amplitude)	VHSDSC		525	625	mV
High-speed data signaling common mode voltage range (guideline for receiver)	Vнsсм		-50	500	mV
High-speed differential input signaling level	See Figure	2-4			
Output levels for high-speed:					
High-speed idle level	VHSOI		-10.0	10	mV
High-speed data signaling high	Vнsон		360	440	mV
High-speed data signaling low	VHSOL		-10.0	10	mV
Chirp J level (different voltage)	VCHIRPJ		700	1100	mV
Chirp K level (different voltage)	Vchirpk		-900	-500	mV

Figure 2-1. Differential Input Sensitivity Range for Low-/Full-Speed

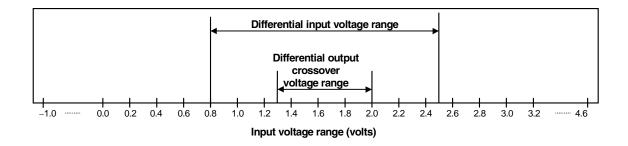
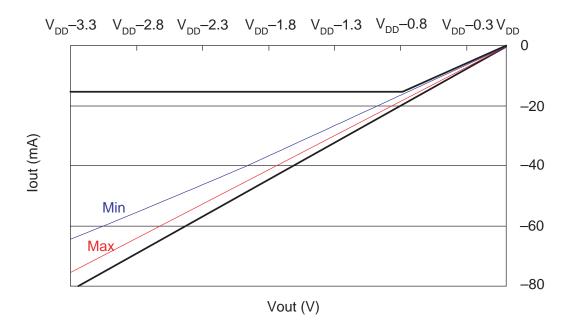


Figure 2-2. Full-Speed Buffer Voh/loh Characteristics for High-Speed Capable Transceiver



Data Sheet S16685EJ2V0DS 15

Figure 2-3. Full-Speed Buffer Vol/Iol Characteristics for High-Speed Capable Transceiver

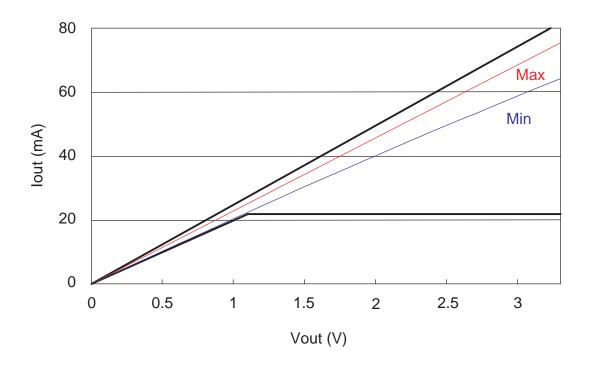
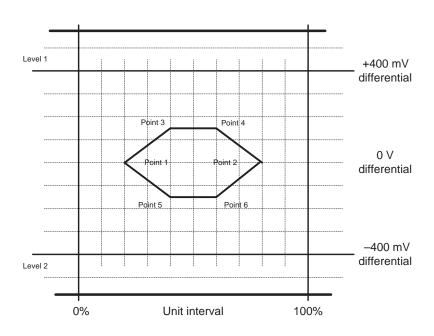


Figure 2-4. Receiver Sensitivity for Transceiver at D+/D-



Test supply voltage $15.8\,\Omega$ 50- Ω To 50-Ω input of a high-speed differential USB Vbus Coax connector D+ oscilloscope, or 50- Ω nearest D- $15.8~\Omega$ outputs of a high-speed device Gnd $50-\Omega$ differential data generator Coax 143 Ω $143~\Omega$

Figure 2-5. Receiver Measurement Fixtures



2.5.2 DC characteristics of BIU

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Off-state output current	loz	Vo = V _{DD} or GND			±10	μΑ
Output short current	los				-250	mA
Input leakage current	lı	VI = VDD or GND		±10 ⁻⁵		μΑ
Output current, low	loL	$V_{OL} = 0.4 V^{Note}$	6			mA
Output current, high	Іон	VoH = 2.4 V	-2			mA
Output voltage, low	Vol	IoL = 0 mA			0.1	V
Output voltage, high	Vон	Iон = 0 mA	V _{DD} -0.2			V

Note 5V-Tolerant Output



2.5.3 Pin capacitance

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	Cin		4.5		6.5	pF
Output/bidirectional capacitance	Соит		8.5		11	pF

Remark These are just estimated values.

2.5.4 Power consumption

Parameter	Symbol	Conditions	i	Min.	Тур.	Max.	Unit
Power consumption	Рн	HS mode	V _{DD}		195	273	mA
			AVDD		12	17	mA
	PF	FS mode	V _{DD}		120	168	mA
			AVDD		12	17	mA
	Ps ₁	Suspend mode 1 ^{Note 1}	V _{DD}		1.5	2.2	mA
			AVDD		0.1	0.2	μΑ
	Ps ₂	Suspend mode 2 ^{Note 2}	V _{DD}		370	520	μΑ
			AVDD		0.1	0.2	μΑ

Notes 1. SND PHY Reg. SPND bit = 1

2. SND PHY Reg. SPND bit = 1

GPR Reg. CONNECTB bit = 0

GPR Reg. PUE bit = 0

BIU Control 0 Reg. OSC_DISCONB bit = 1



2.6 AC Characteristics (T_A = 0 to \pm 70°C, V_{DD} = 3.3 V \pm 10%)

The AC characteristics are classified into those of the USB interface block and those of the BIU.

2.6.1 Overall AC characteristics and those of BIU

(1) Clock

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Clock frequency	f _{CLK}	X'tal	-500ppm	30	+500ppm	MHz
		Oscillator block	-500ppm	30	+500ppm	MHz
Clock Duty cycle	T _{DUTY}		40	50	60	%

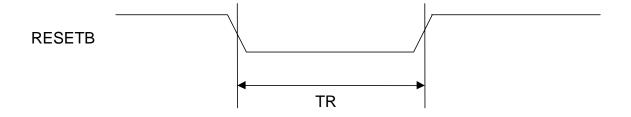
Remarks 1. Reccomended accurarcy of clock frequency is ± 100 ppm.

2. Required accuracy of X'tal or Oscillator block is includeing initial frequency accuracy, the spread of X'tal capacityor loading, supply voltage, temperature, and aging etc.

(2) Reset

Symbol	Specification	Min.	Тур.	Max.	Unit
TR	Reset width	2			μs

HW reset timing





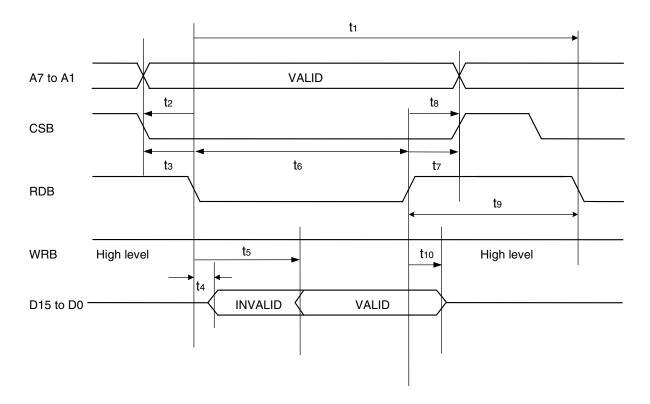
2.6.2 AC characteristics of BIU block with Function 1 selected

(1) CPU BUS read operation

Symbol	Parameter	Min.	Тур.	Max.	Unit
T1	Read cycle time	91		∞	ns
T2	Address setup time (RDB↓)	5		∞	ns
Т3	Chip select setup time (RDB↓)	5		∞	ns
T4	Buffer direction change time (RDB↓)	-		14	ns
T5	Output data delay time (RDB↓)	-		57	ns
T6	Read command width	57		∞	ns
T7	Chip select hold time (RDB↑)	5		∞	ns
T8	Address hold time (RDB↑)	5		∞	ns
Т9	RDB inactive time	34		∞	ns
T10	Output data hold time (RDB↑)	4		-	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

CPU bus read timing



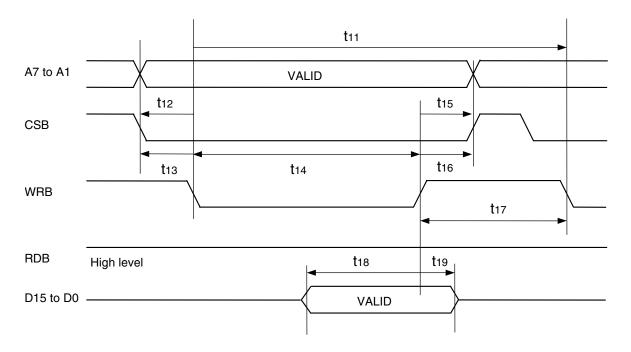


(2) CPU bus write operation

Symbol	Parameter	Min.	Тур.	Max.	Unit
T11	Write cycle time	68		∞	ns
T12	Address setup time (WRB↓)	5		∞	ns
T13	Chip select setup time (WRB↓)	5		∞	ns
T14	Write command width	34		∞	ns
T15	Address hold time (WRB↑)	5		∞	ns
T16	Chip select hold time (WRB↑)	5		∞	ns
T17	WRB inactive time	34		∞	ns
T18	Input data setup time	10		∞	ns
T19	Input data hold time	0		~	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

CPU bus write timing



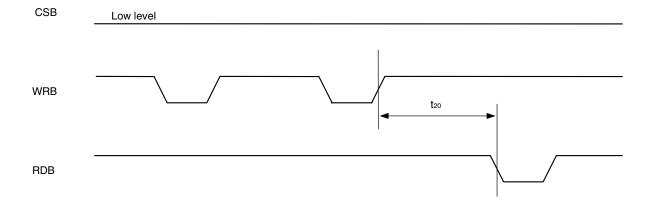


(3) CPU BUS RDB vs. WRB timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
T20	WRB vs. RDB inactive time	34		∞	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

CPU bus read vs. write change timing





(4) CPU bus DMA transfer

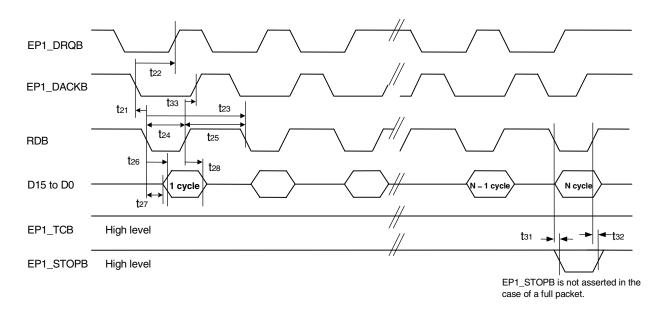
(a) CPU bus DMA single mode read transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
T21	DMA request acknowledge setup time (RDB↓)	0		∞	ns
T22	DMA request off time (EP1_DACKB↓)	_		54	ns
T23	DMA single mode read transfer cycle time	91		∞	ns
T24	Read command width	57		∞	ns
T25	Read command inactive time	34		∞	ns
T26	Read data delay time (RDB↓)	_		57	ns
T27	Buffer direction change time (RDB↓)	_		14	ns
T28	Read data hold time (RDB↑)	4		-	ns
T29	EP1_TCB setup time (RDB↓)	0		Note	ns
T30	EP1_TCB hold time (RDB↓)	17		∞	ns
T31	EP1_STOPB delay time (RDB↓)	_		15	ns
T32	EP1_STOPB OFF delay time (RDB↑)	3		-	ns
T33	DMA request acknowledge hold time (RDB↑)	0		∞	ns
T34	Undefined	_		_	ns

Note Can be input after previous RDB1.

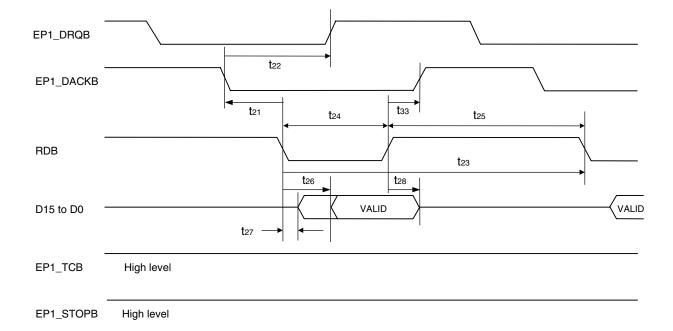
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

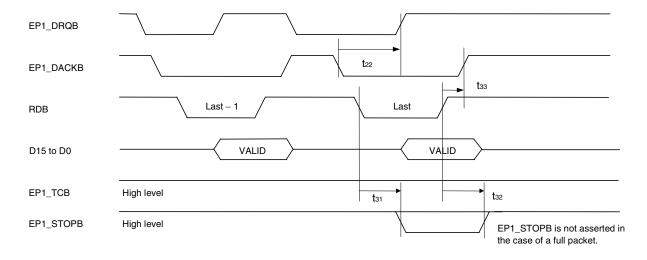




(Start timing)

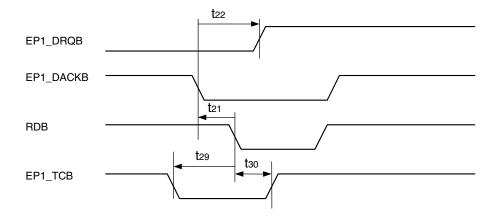


(End timing)





(TCB timing)





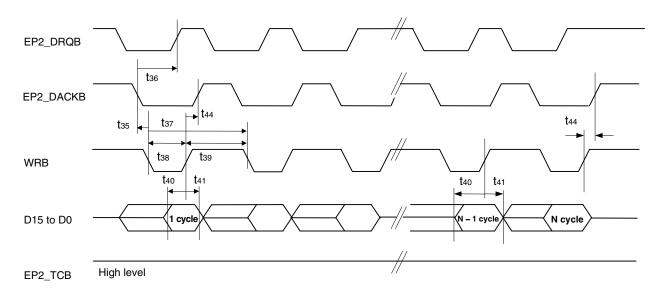
(b) CPU bus DMA single mode write transfer

Symbol	Parameter	Min.	Тур.	Max.	Unit
T35	DMA request acknowledge setup time (WRB↓)	0		∞	ns
T36	DMA request off time (EP2_DACKB↓)	_		54	ns
T37	DMA single mode write transfer cycle time	88		∞	ns
T38	Write command width	54		∞	ns
T39	Write command inactive time	34		∞	ns
T40	Write data setup time (WRB↑)	10		∞	ns
T41	Write data hold time (WRB [↑])	0		∞	ns
T42	EP2_TCB setup time (WRB↓)	0		Note	ns
T43	EP2_TCB hold time (WRB↓)	17		∞	ns
T44	DMA request acknowledge hold time (WRB↑)	0		∞	ns

Note Can be input after immediately previous WRB1.

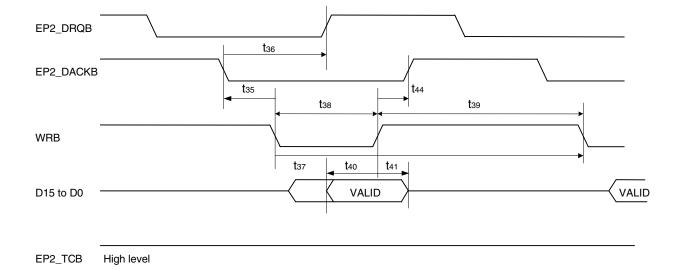
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

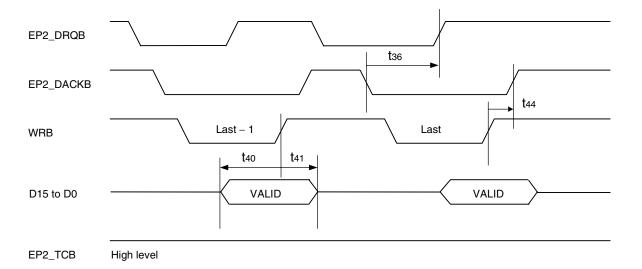




(Start timing)

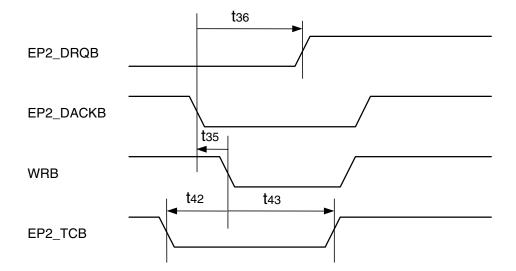


(End timing)





(TCB timing)





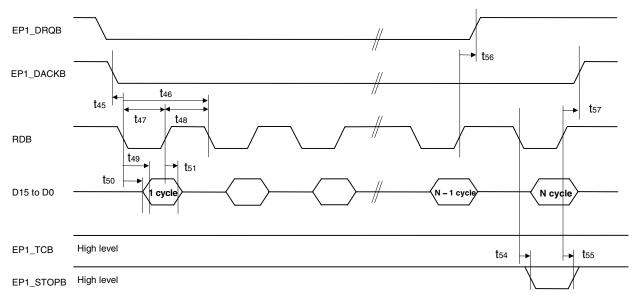
(c) CPU bus DMA demand read transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
T45	DMA request acknowledge setup time (RDB↓)	0		∞	ns
T46	DMA demand mode read transfer cycle time	91		∞	ns
T47	Read command width	57		∞	ns
T48	Read command inactive time	34		∞	ns
T49	Read data delay time (RDB↓)	-		57	ns
T50	Buffer direction change time (RDB↓)	-		14	ns
T51	Read data hold time (RDB [↑])	4		-	ns
T52	EP1_TCB setup time (RDB↓)	0		Note	ns
T53	EP1_TCB hold time (RDB↓)	17		∞	ns
T54	EP1_STOPB delay time (RDB↓)	-		15	ns
T55	EP1_STOPB delay time (RDB↑)	3		_	ns
T56	DMA request off time (RDB↑)	-		59	ns
T57	DMA request acknowledge hold time (RDB↑)	0		∞	ns
T69	DMA request off time (EP1_DACKB↓)	-		38	ns
T71	DMA request off time (EP1_DACKB↓) 1 cycle transfer	-		38	ns
T72	DMA request on time (EP1_DACKB↑)	-		88	ns
T74	DMA request off time (RDB↓)	-		60	ns

Note Can be input after immediately previous RDB1.

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

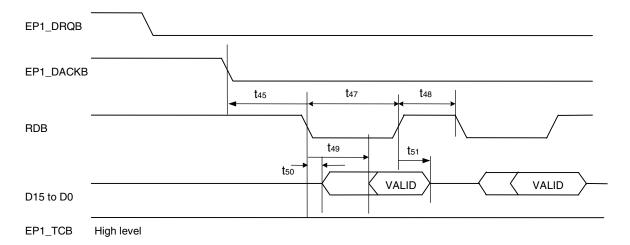
(Overall)



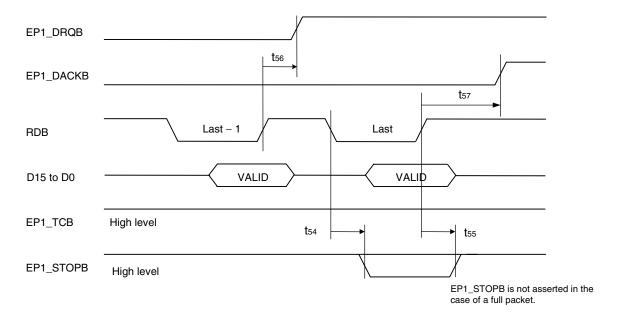
EP1_STOPB is not asserted in the case of a full packet.



(Start timing)

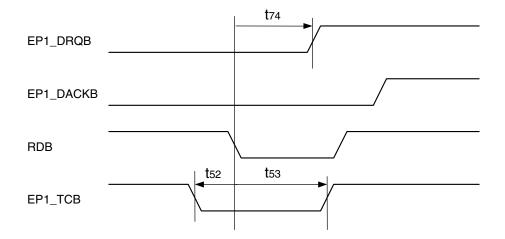


(End timing)

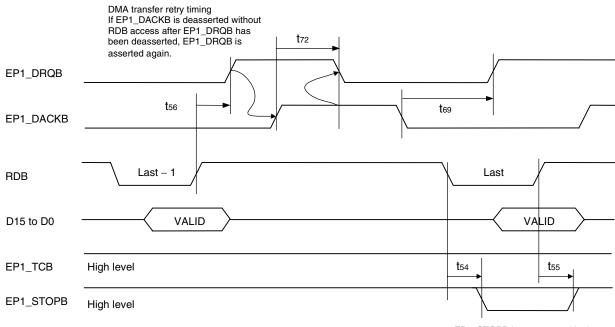




(TCB timing)



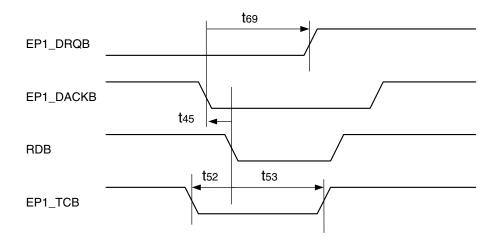
(Retransmission timing)



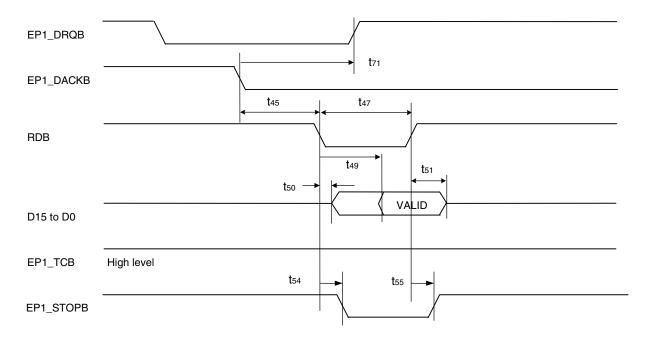
EP1_STOPB is not asserted in the case of a full packet.



(If EP1_TCB is input when retransmission is executed)



(One-cycle transfer)





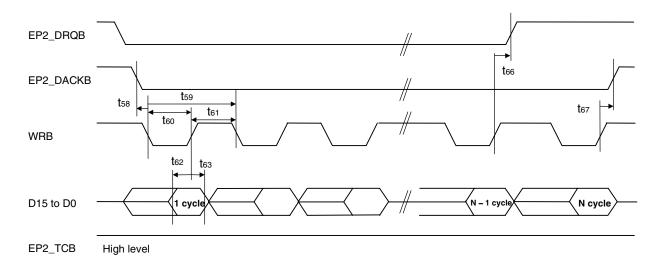
(d) CPU bus DMA demand write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
T58	DMA request acknowledge setup time (WRB↓)	0		∞	ns
T59	DMA demand mode write transfer cycle time	72		∞	ns
T60	Write command width	38		∞	ns
T61	Write command inactive time	34		∞	ns
T62	Write data setup time (WRB↑)	10		∞	ns
T63	Write data hold time (WRB1)	0		∞	ns
T64	EP2_TCB setup time (WRB↓)	0		Note	ns
T65	EP2_TCB hold time (WRB↓)	17		∞	ns
T66	DMA request off time (WRB↑)	_		60	ns
T67	DMA request acknowledge hold time (WRB↑)	0		∞	ns
T70	DMA request off time (EP2_DACKB↓)	_		38	ns
T73	DMA request on time (EP2_DACKB↑)	_		88	ns
T75	DMA request off time (WRB↓)	_		60	ns

Note Can be input after immediately previous WRB1.

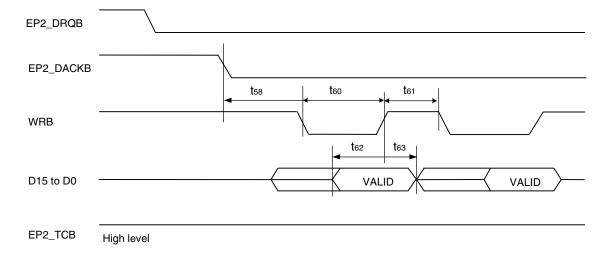
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

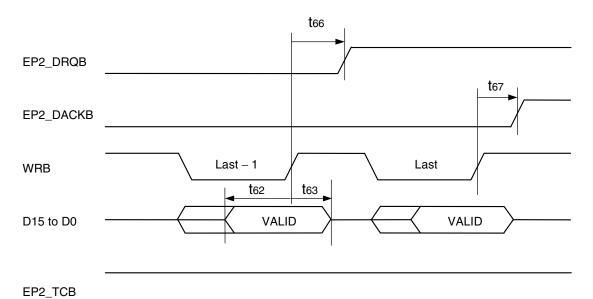




(Start timing)

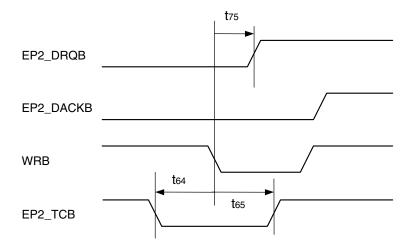


(End timing)

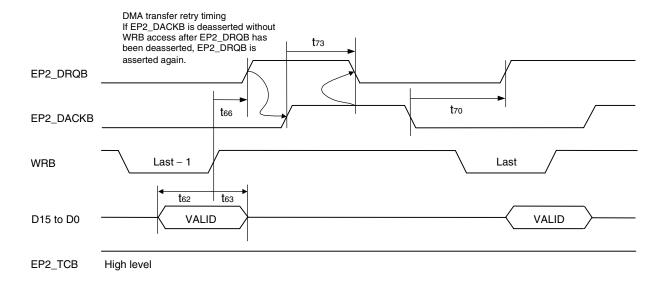




(TCB timing)

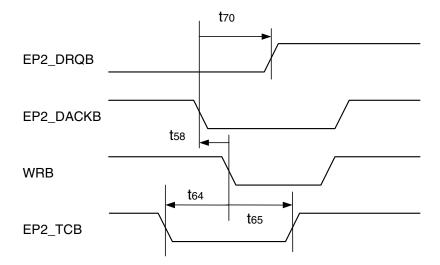


(Retransmission timing)





(If EP1_TCB is input when retransmission is executed)

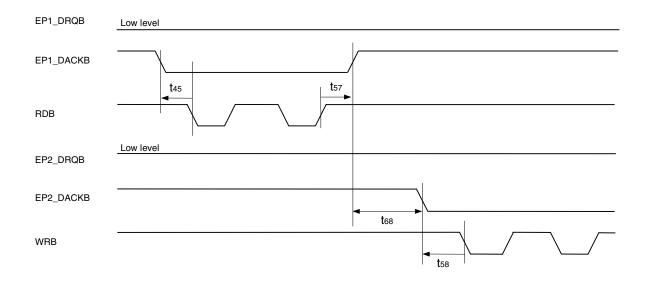




(a) CPU bus DMA read transfer vs. write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
T68	RDB vs. WRB command inactive time	34		∞	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).





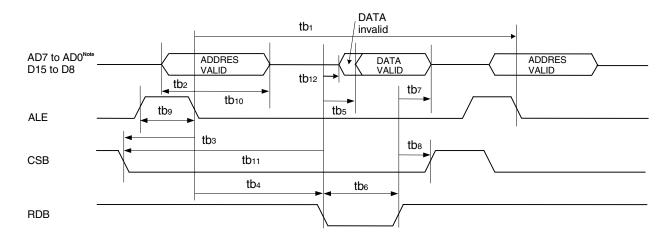
2.6.3 AC characteristics of BIU block with function 2 or 3 selected

(1) CPU bus read operation

Symbol	Parameter	Min.	Тур.	Max.	Unit
TB1	Read cycle time	86		∞	ns
TB2	Address setup time (ALE↓)	10		∞	ns
TB3	Chip select setup time (ALE↓)	17		∞	ns
TB4	Read command delay time (ALE↓)	7		∞	ns
TB5	Output data delay time (RDB↓)	_		57	ns
TB6	Read command width	57		∞	ns
TB7	Output data hold time (RDB [↑])	4		-	ns
TB8	Chip select hold time (RDB↑)	5		∞	ns
TB9	ALE width	10		∞	ns
TB10	Address hold time (ALE↓)	0		∞	ns
TB11	Chip select setup time (RDB↓)	5		∞	ns
TB12	Buffer direction change time (RDB↓)	_		14	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

CPU bus read timing



Note D7 to D0 for Function 2

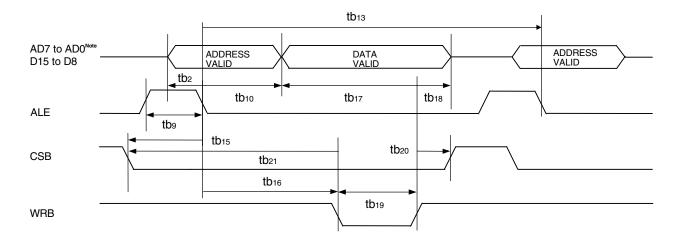


(2) CPU bus write operation

Symbol	Parameter	Min.	Тур.	Max.	Unit
TB13	Write cycle time	58		∞	ns
TB14	Address setup time (ALE↓)	17		∞	ns
TB15	Chip select setup time (ALE↓)	17		∞	ns
TB16	Write command delay time (ALE↓)	7		∞	ns
TB17	Input data setup time (WRB↑)	10		∞	ns
TB18	Input data hold time (WRB↑)	0		∞	ns
TB19	Write command width	34		∞	ns
TB20	Chip select hold time (WRB↑)	0		∞	ns
TB21	Chip select setup time (WRB↓)	5		8	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

CPU bus write timing



Note D7 to D0 for Function 2



2.6.4 External local bus

(1) External local bus 16-bit mode

(a) External local bus 16-bit mode DMA single mode read transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L16T21	DMA request acknowledge setup time (EP1_RDB↓)	0		∞	ns
L16T22	DMA request off time 1 (EP1_DACKB↓)	_		54	ns
L16T23	DMA single mode read transfer cycle time	91		∞	ns
L16T24	Read command width	57		∞	ns
L16T25	Read command inactive time	34		∞	ns
L16T26	Read data delay time (EP1_RDB↓)	_		57	ns
L16T27	Buffer direction change time (EP1_RDB↓)	_		14	ns
L16T28	Read data hold time (EP1_RDB↑)	4			ns
L16T29	EP1_TCB setup time (EP1_RDB↓)	0		Note	ns
L16T30	EP1_TCB hold time (EP1_RDB↓)	17		∞	ns
L16T31	EP1_STOPB delay time (EP1_RDB↓)	_		15	ns
L16T32	EP1_STOPB delay time (EP1_RDB↑)	3		-	ns
L16T33	DMA request acknowledge hold time (EP1_RDB↑)	0		∞	ns
L16T34	Undefined	_		_	ns

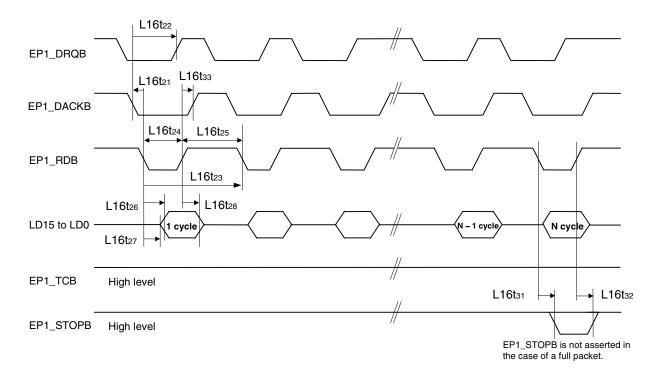
Note Can be input after previous EP1_RDB↑.

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

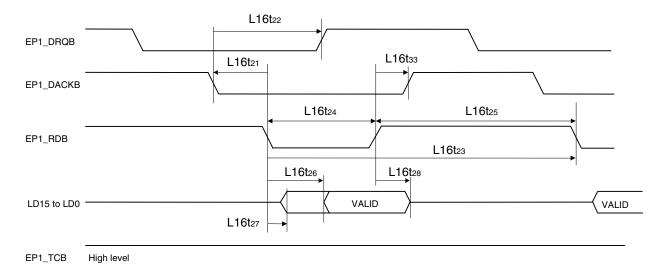
Data Sheet S16685EJ2V0DS 41



(Overall)

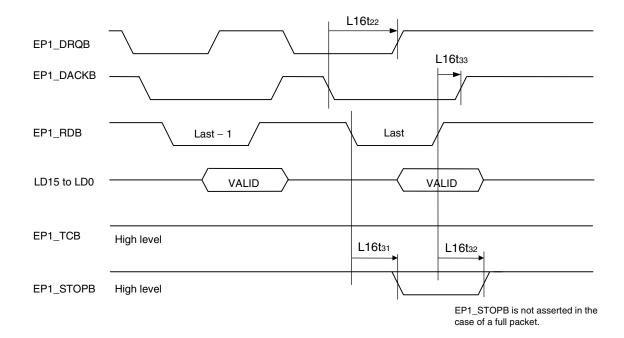


(Start timing)

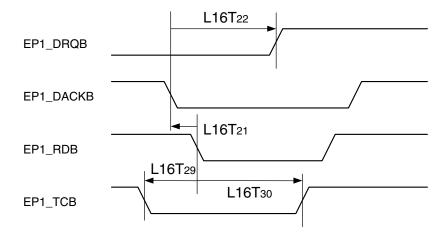




(End timing)



(TCB timing)





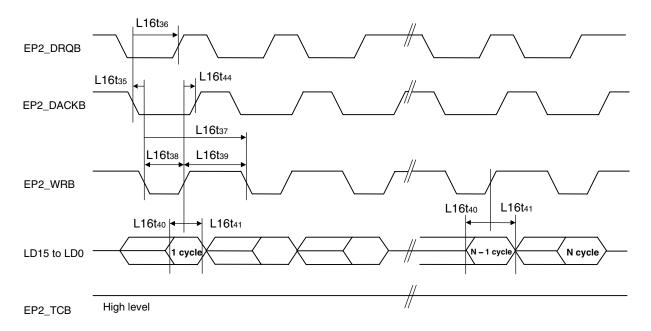
(a) External local bus 16-bit mode DMA single mode write transfer

Symbol	Parameter	Min.	Тур.	Max.	Unit
L16T35	DMA request acknowledge setup time (EP2_WRB↓)	0		∞	ns
L16T36	DMA request off time 1 (EP2_DACKB↓)	_		54	ns
L16T37	DMA single mode write transfer cycle time	88		∞	ns
L16T38	Write command width	54		∞	ns
L16T39	Write command inactive time	34		∞	ns
L16T40	Write data setup time (EP2_WRB↑)	10		∞	ns
L16T41	Write data hold time (EP2_WRB↑)	0		∞	ns
L16T42	EP2_TCB setup time (EP2_WRB↓)	0		Note	ns
L16T43	EP2_TCB hold time (EP2_WRB↓)	17		∞	ns
L16T44	DMA request acknowledge hold time (EP2_WRB [↑])	0		∞	ns

Note Can be input after previous EP2_WRB[↑].

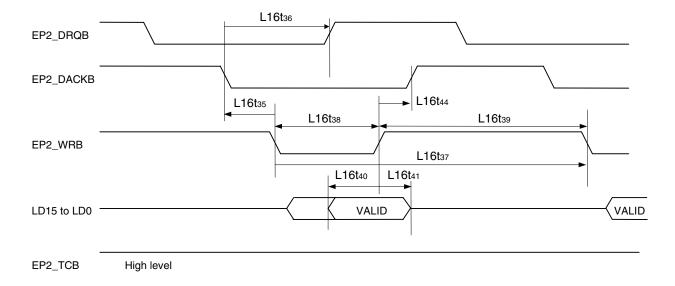
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

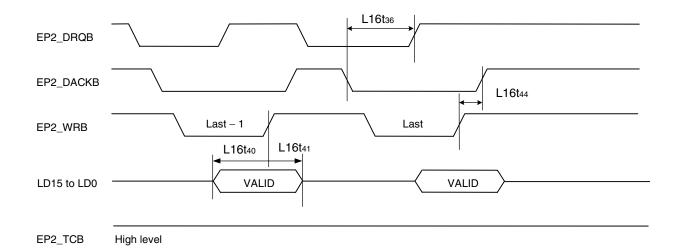




(Start timing)

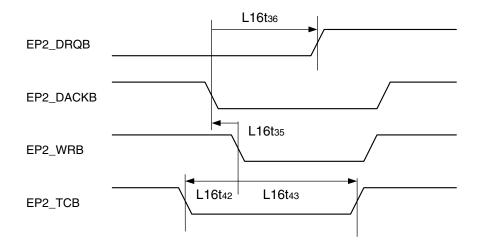


(End timing)





(TCB timing)





(c) External local bus 16-bit mode DMA demand read transfer timing

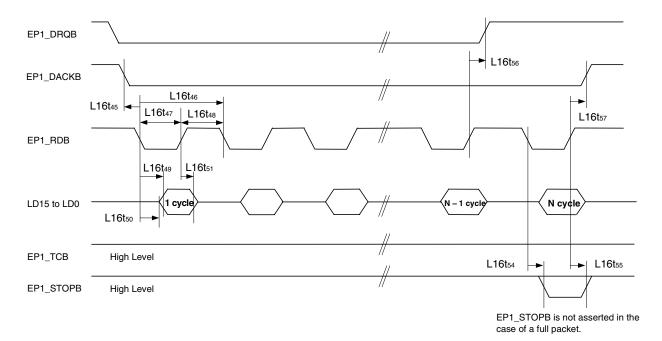
Symbol	Parameter	Min.	Тур.	Max.	Unit
L16T45	DMA request acknowledge setup time (EP1_RDB↓)	0		∞	ns
L16T46	DMA demand mode read transfer cycle time	91		∞	ns
L16T47	Read command width	57		8	ns
L16T48	Read command inactive time	34		∞	ns
L16T49	Read data delay time (EP1_RDB↓)	-		57	ns
L16T50	Buffer direction change time (EP1_RDB↓)	-		14	ns
L16T51	Read data hold time (EP1_RDB↑)	4		-	ns
L16T52	EP1_TCB setup time (EP1_RDB↓)	0		Note	ns
L16T53	EP1_TCB hold time (EP1_RDB↓)	17		∞	ns
L16T54	EP1_STOPB delay time (EP1_RDB↓)	_		15	ns
L16T55	EP1_STOPB delay time (EP1_RDB↑)	3		_	ns
L16T56	DMA request off time (EP1_RDB↑)	-		59	ns
L16T57	DMA request acknowledge hold time (EP1_RDB↑)	0		∞	ns
L16T69	DMA request off time (EP1_DACKB↓)	_		38	ns
L16T71	DMA request off time (EP1_DACKB↓) 1 cycle transfer	-		38	ns
L16T72	DMA request on time (EP1_DACKB1)	-		88	ns
L16T74	DMA request off time (EP1_RDB↓)	-		60	ns

Note Can be input after immediately previous EP1_RDB↑.

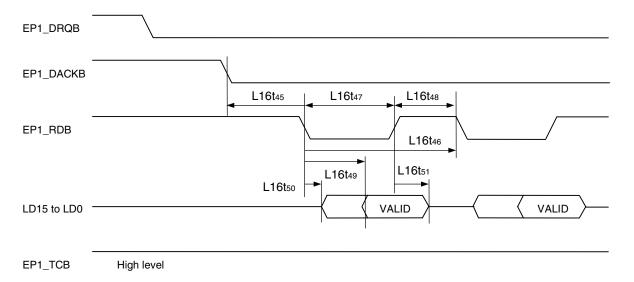
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).



(Overall)

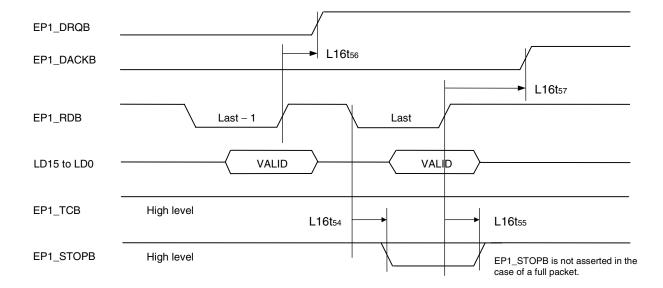


(Start timing)

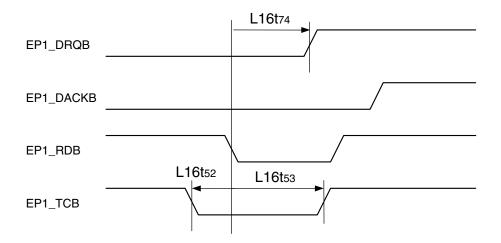




(End timing)

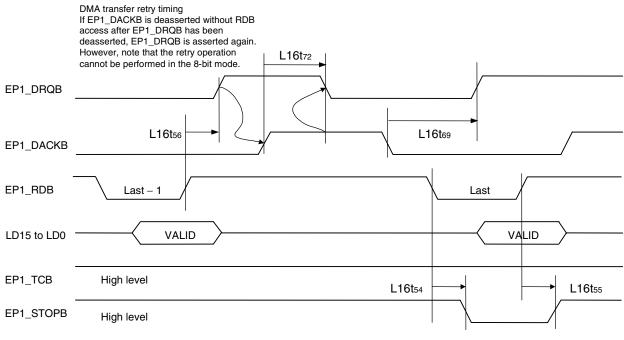


(TCB timing)



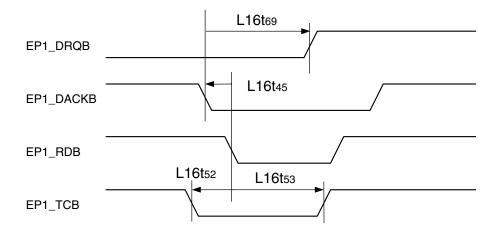


(Retransmission timing)



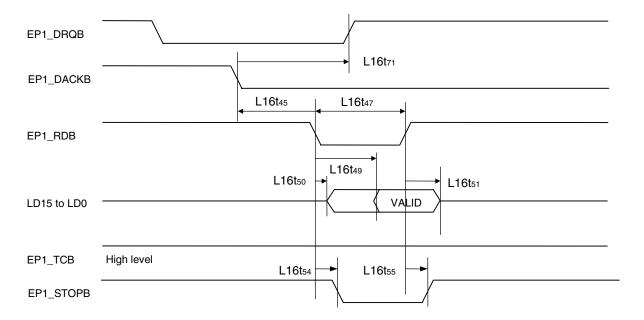
EP1_STOPB is not asserted in the case of a full packet.

(If EP1_TCB is input when retransmission is executed)





(One-cycle transfer)





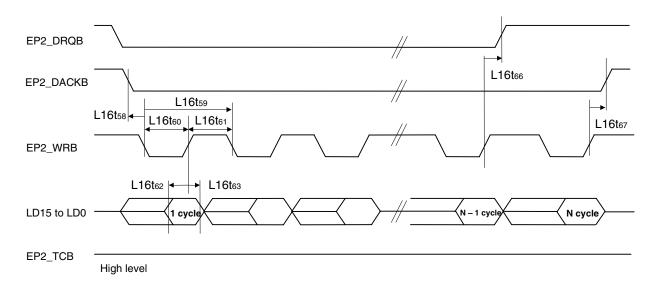
(d) External local bus 16-bit mode DMA demand write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L16T58	DMA request acknowledge setup time (EP2_WRB↓)	0		∞	ns
L16T59	DMA demand mode write transfer cycle time	72		~	ns
L16T60	Write command width	38		∞	ns
L16T61	Write command inactive time	34		∞	ns
L16T62	Write data setup time (EP2_WRB↑)	10		∞	ns
L16T63	Write data hold time (EP2_WRB↑)	0		∞	ns
L16T64	EP2_TCB setup time (EP2_WRB↓)	0		Note	ns
L16T65	EP2_TCB hold time (EP2_WRB↓)	17		∞	ns
L16T66	DMA request off time (EP2_WRB↑)	-		60	ns
L16T67	DMA request acknowledge hold time (EP2_WRB1)	0		∞	ns
L16T70	DMA request off time (EP2_DACKB↓)	-		38	ns
L16T73	DMA request on time (EP2_DACKB1)	_		88	ns
L16T75	DMA request off time (EP2_WRB↓)	_		60	ns

Note Can be input after previous EP2_WRB↑.

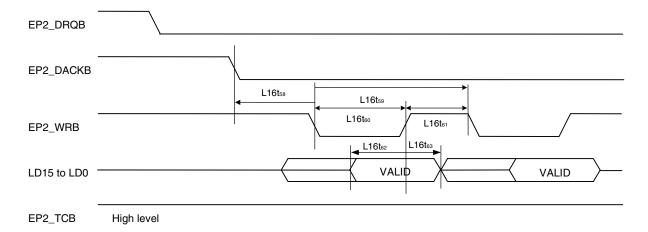
Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

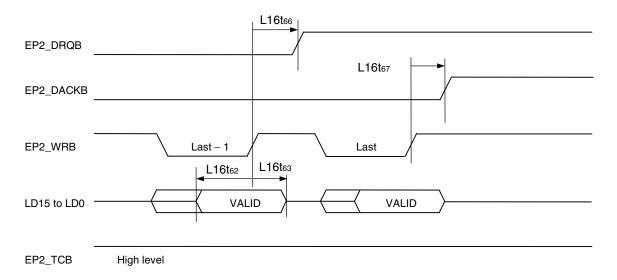




(Start timing)

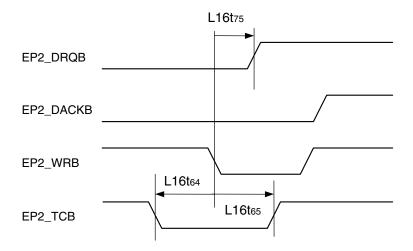


(End timing)

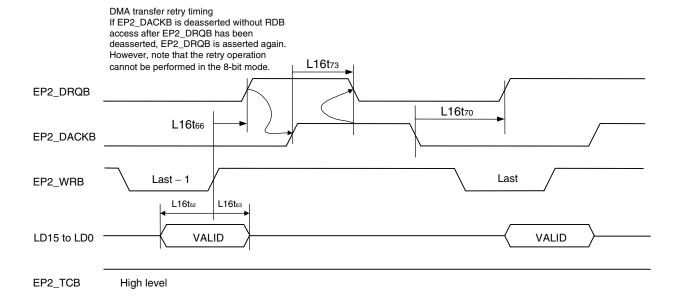




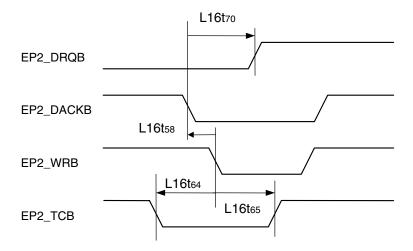
(TCB timing)



(Retransmission timing)



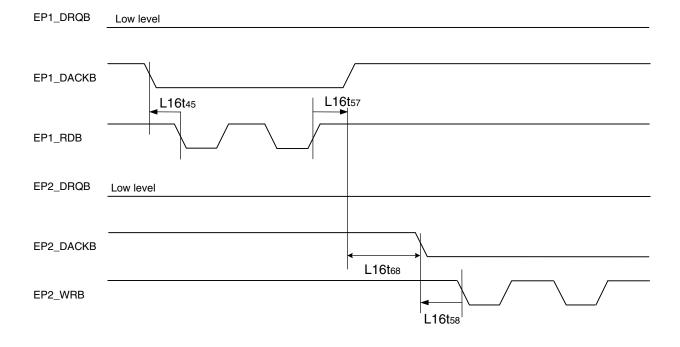
(If EP1_TCB is input when retransmission is executed)



(e) External local bus 16-bit mode DMA EP1_Read transfer vs. EP2_Write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L16T68	EP1_RDB vs. EP2_WRB command inactive time	34		8	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).





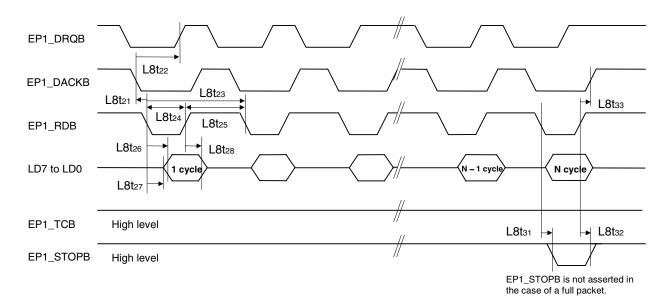
(2) External local bus 8-bit mode

(a) External local bus 8-bit mode DMA single mode read transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L8T21	DMA request acknowledge setup time (EP1_RDB↓)	0		∞	ns
L8T22	DMA request off time 1 (EP1_DACKB↓)	ı		10	ns
L8T23	DMA single mode read transfer cycle time	91		8	ns
L8T24	Read command width	57		8	ns
L8T25	Read command inactive time	34		∞	ns
L8T26	Read data delay time (EP1_RDB↓)	ı		57	ns
L8T27	Buffer direction change time (EP1_RDB↓)	I		14	ns
L8T28	Read data hold time (EP1_RDB↑)	4		_	ns
L8T31	EP1_STOPB delay time (EP1_RDB↓)	-		15	ns
L8T32	EP1_STOPB delay time (EP1_RDB↑)	3		_	ns
L8T33	DMA request acknowledge hold time (EP1_RDB↑)	0		8	ns
L8T34	Undefined	_		_	ns

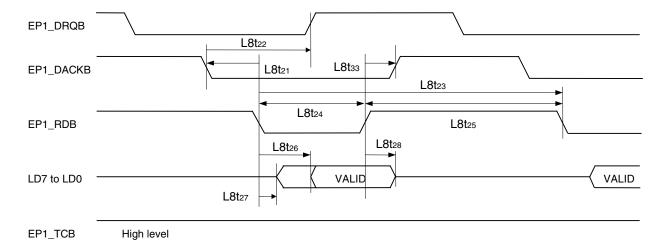
- **Remarks 1.** Use of EP1_TCB is prohibited in the 8-bit external local bus mode. Clamp this signal to the inactive status.
 - 2. LD15 to 8 are undefined in the 8-bit external local bus mode (these signals are invalid when input and undefined when output).
 - 3. It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

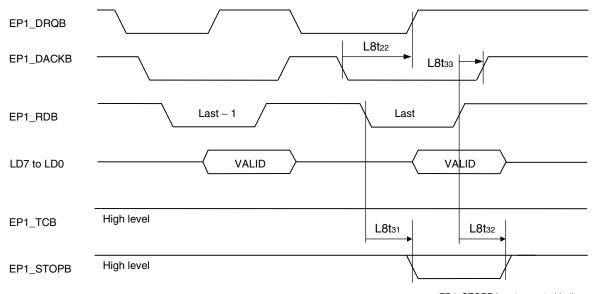




(Start timing)



(End timing)



EP1_STOPB is not asserted in the case of a full packet.



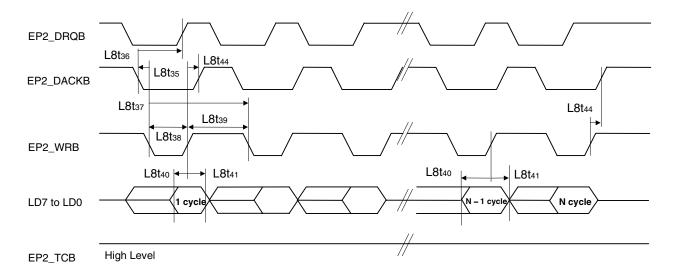
(b) External local bus 8-bit mode DMA single mode write transfer

Symbol	Parameter	Min.	Тур.	Max.	Unit
L8T35	DMA request acknowledge setup time (EP2_WRB↓)	0		∞	ns
L8T36	DMA request off time 1 (EP2_DACKB↓)	-		54 ^{Note}	ns
L8T37	DMA single mode write transfer cycle time	88		∞	ns
L8T38	Write command width	54		8	ns
L8T39	Write command inactive time	34		∞	ns
L8T40	Write data setup time (EP2_WRB↑)	10		∞	ns
L8T41	Write data hold time (EP2_WRB↑)	0		∞	ns
L8T44	DMA request acknowledge hold time (EP2_WRB↑)	0		∞	ns

- **Remarks 1.** Use of EP1_TCB is prohibited in the 8-bit external local bus mode. Clamp this signal to the inactive status.
 - 2. LD15 to 8 are undefined in the 8-bit external local bus mode (these signals are invalid when input and undefined when output).
 - 3. It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

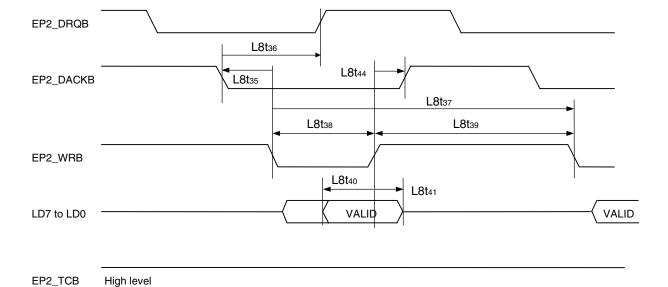
Note The difference in specifications when compared with L8T22 is that BIU processing is performed for EP1 and that EPC2 processing is performed for EP2.

(Overall)

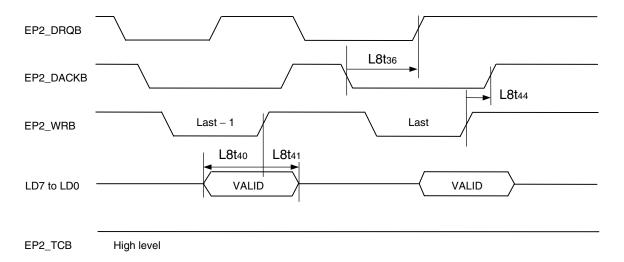




(Start timing)



(End timing)



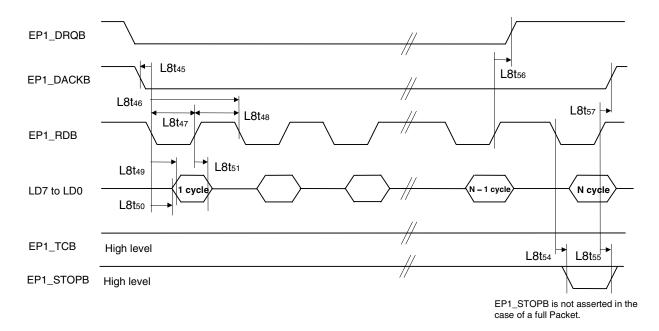


(c) External local bus 8-bit mode DMA demand read transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L8T45	DMA request acknowledge setup time (EP1_RDB↓)	0		∞	ns
L8T46	DMA demand mode read transfer cycle time	90		∞	ns
L8T47	Read command width	56		∞	ns
L8T48	Read command inactive time	34		∞	ns
L8T49	Read data delay time (EP1_RDB↓)	ı		56	ns
L8T50	Buffer direction change time (EP1_RDB↓)	ı		14	ns
L8T51	Read data hold time (EP1_RDB↑)	4		=	ns
L8T54	EP1_STOPB delay time (EP1_RDB↓)	-		15	ns
L8T55	EP1_STOPB delay time (EP1_RDB↑)	3		-	ns
L8T56	DMA request off time (EP1_RDB↑)	ı		60	ns
L8T57	DMA request acknowledge hold time (EP1_RDB↑)	0		∞	ns

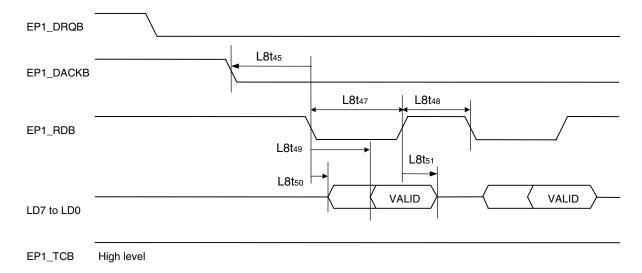
- **Remarks 1.** Use of EP1_TCB is prohibited in the 8-bit external local bus mode. Clamp this signal to the inactive status.
 - 2. LD15 to 8 are undefined in the 8-bit external local bus mode (these signals are invalid when input and undefined when output).
 - 3. It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

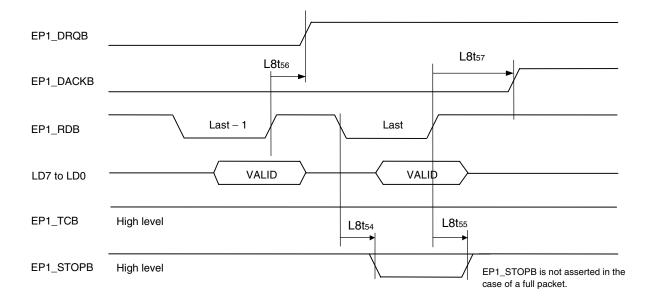




(Start timing)



(End timing)



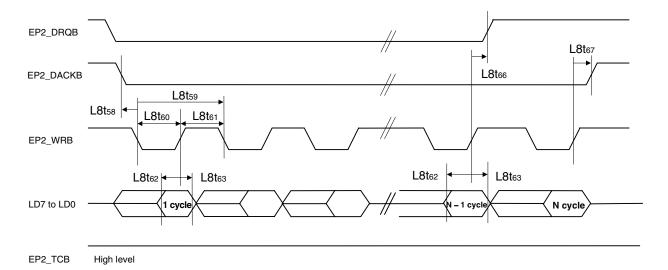


(d) External local bus 8-bit mode DMA demand write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L8T58	DMA request acknowledge setup time (EP2_WRB↓)	0		∞	ns
L8T59	DMA demand mode write transfer cycle time	72		∞	ns
L8T60	Write command width	38		8	ns
L8T61	Write command inactive time	34		∞	ns
L8T62	Write data setup time (EP2_WRB↑)	10		∞	ns
L8T63	Write data hold time (EP2_WRB1)	0		8	ns
L8T66	DMA request off time (EP2_WRB↑)	_		60	ns
L8T67	DMA request acknowledge hold time (EP2_WRB↑)	0		∞	ns

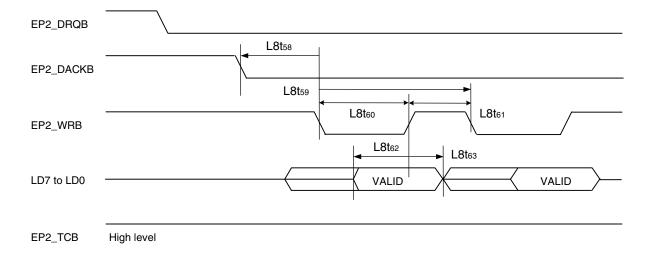
- **Remarks 1.** Use of EP1_TCB is prohibited in the 8-bit external local bus mode. Clamp this signal to the inactive status.
 - 2. LD15 to 8 are undefined in the 8-bit external local bus mode (these signals are invalid when input and undefined when output).
 - 3. It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).

(Overall)

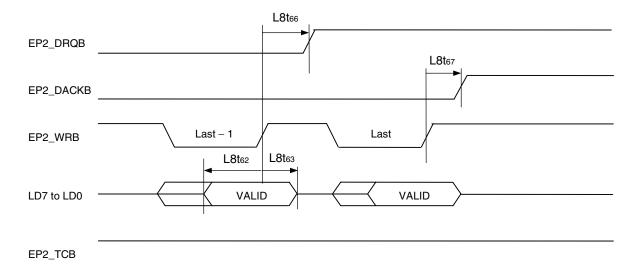




(Start timing)



(End timing)

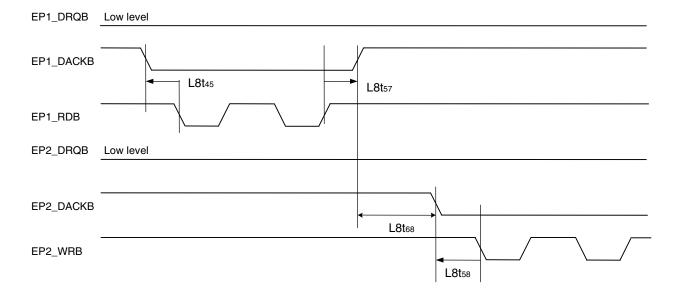




(e) External local bus 8-bit mode DMA EP1_Read transfer vs. EP2_Write transfer timing

Symbol	Parameter	Min.	Тур.	Max.	Unit
L8T68	EP1_RDB vs. EP2_WRB command inactive time	34		8	ns

Remark It is assumed that the external pin capacitance is 15 pF (data bus = 50 pF).





2.6.5 USB interface timing

Parameter	Symbol	Conditions	Min.	Max.	Unit
Full-speed source electrical characteristic	s				
Rise time	T _{FR}	$C_L = 50 \text{ pF},$ $R_S = 36 \Omega$	4	20	ns
Fall time	TFF	$C_L = 50 \text{ pF},$ $Rs = 36 \Omega$	4	20	ns
Differential rise and fall time matching	TFRFM	(Tfr/Tff)	90	111.11	%
Full-speed data rate for hubs and devices that are high-speed capable	TFDRATHS	Average bit rate	11.9940	12.0060	Mb/s
Frame interval	TFRAME		0.9995	1.0005	ms
Consecutive frame interval jitter	T _{RFI}	No clock adjustment		42	ns
Source jitter total (including frequency tolerance):					
To next transition	T _{DJ1}		-3.5	3.5	ns
For paired transitions	T _{DJ2}		-4.0	4.0	ns
Source jitter for differential transition to SE0 transition	TFDEOP		-2	5	ns
Receiver jitter:					
To next transition	T _{JR1}		-18.5	18.5	ns
For paired transitions	T _{JR2}		-9	9	ns
Source SE0 interval of EOP	Теорт		160	175	ns
Receiver SE0 interval of EOP	TFEOPR		82		ns
Width of SE0 interval during differential transition	T _{FST}			14	ns
High-speed source electrical characteristi	cs				
Rise time (10% to 90%)	THSR		500		ps
Fall time (10% to 90%)	THSF		500		ps
Driver waveform requirements	See Figure	2-6	<u> </u>		
High-speed data rate	THSDRAT		479.760	480.240	Mb/s
Microframe interval	THSFRAM		124.9375	125.0625	μs
Consecutive microframe interval difference	THSRFI			4 high-speed	Bit times
Data source jitter	See Figure 2-6.				
Receiver jitter tolerance	See Figure	2-4.			



Parameter	Symbol	Conditions	Min.	Max.	Unit
Device event timing					
Time from internal power good to device pulling D+/D- beyond V _{IHZ} (min.) (signaling attach)	Tsigatt			100	ms
Debounce interval provided by USB system software after attach	Таттов			100	ms
Inter-packet delay (for low-/full-speed)	T _{IPD}		2		Bit times
Inter-packet delay for device response w/detachable cable for low-/full-speed	TRSPIPD1			6.5	Bit times
High-speed detection start time from suspend	Tsca		2.5		μs
Sample time for suspend vs. reset	Tcsr		100	875	μs
Power down under suspend	Tsus			10	ms
SUSPEND set time (SPNDOUT)	Tssp		0	_	
SUSPEND clear time (RSUMOUT)	Tcsp		0	_	
Reversion time from suspend to high-speed	T _{RHS}			1.333	μs
SUSPEND setup time (RSUMIN)	Tsrw		0	_	
RSUMIN active pulse width	T _{RWP}		1	15	ms
Drive chirp K width	Тско		1		ms
Finish chirp K assertion	TFCA			7	ms
Start sequencing chirp K-J-K-J-K-J	Tssc			100	μs
Finish sequencing chirp K-J	T _{FSC}		-500	-100	μs
Detect sequencing chirp K-J width	Tcsı		2.5		μs
Sample time for sequencing chirp	Tscs		1.0	2.5	ms
Reversion time to high-speed	Тпна			500	μs
High-speed detection start time	T _{HDS}		2.5	3000	μs
Reset completed time	TDRS		10		ms

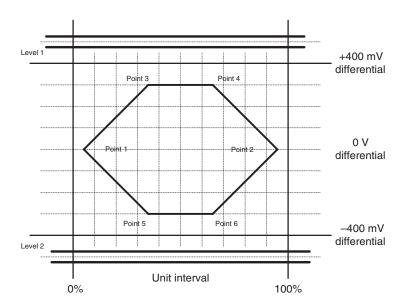
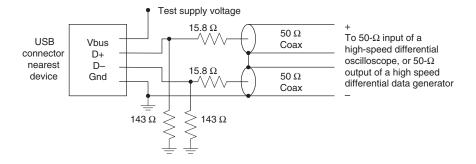


Figure 2-6. Transmit Waveform for Transceiver at D+/D-

Figure 2-7. Transmitter Measurement Fixtures

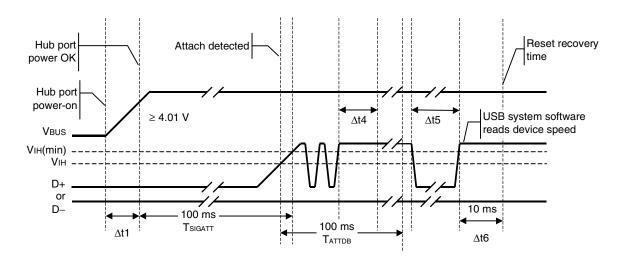


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(1) Power-on and connection events

Figure 2-8. Power-on and Connection Event Timing



(2) USB signals

Figure 2-9. USB Differential Data Jitter for Full-Speed

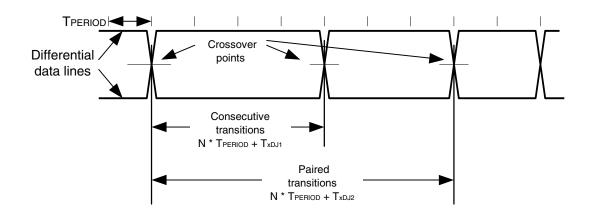
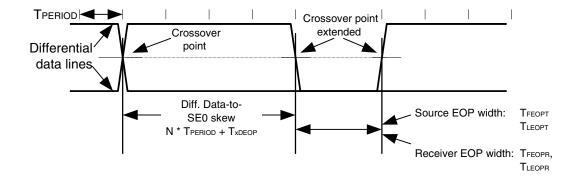


Figure 2-10. USB Differential-to-EOP Transition Skew and EOP Width for Full-Speed



Differential data lines

Consecutive transitions

N * TPERIOD + TxJR1

Paired transitions

N * TPERIOD + TxJR2

Figure 2-11. USB Receiver Jitter Tolerance for Full-Speed

(3) USB connection sequence on USB1.1 bus

The PHY core implemented on the μ PD720122 automatically determines the Up port.

Check the SP_MODE bit (SP_MODE) of the Int Status 2 register after an EPC2_STG bus reset interrupt has occurred to determine whether the USB is connected to FS or HS.

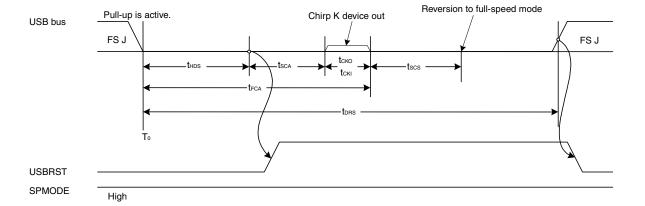
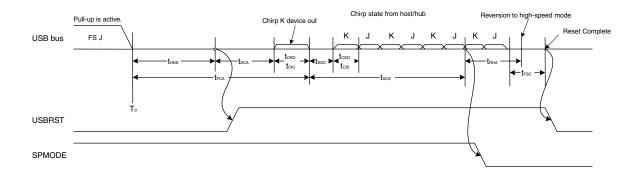


Figure 2-12. USB Connection Sequence on USB 1.1 Bus



(4) USB connection sequence on USB 2.0 bus

Figure 2-13. USB Connection Sequence on USB 2.0 Bus



(5) Bus reset sequence (1)

The bus reset sequence when connected to a USB 1.1 bus is shown below.

Pull-up is inactive.
High-speed packet

USB bus

Reversion to full-speed mode

Chirp K device out

FS J

To

USBRST

SPMODE

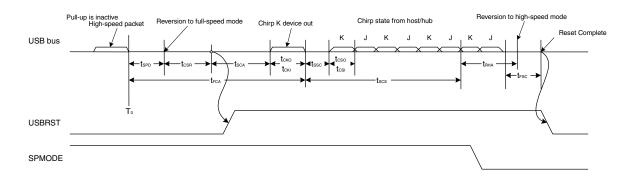
Figure 2-14. Bus Reset Sequence (1)



(6) Bus reset sequence (2)

The bus reset sequence when connected to a USB 2.0 bus is shown below.

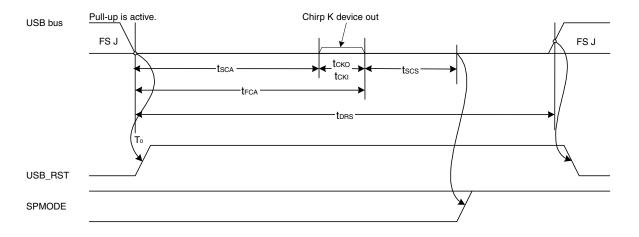
Figure 2-15. Bus Reset Sequence (2)





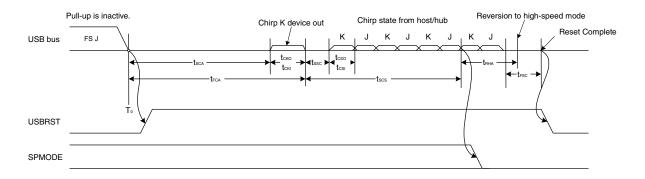
(7) USB reset from suspend state (1)

Figure 2-16. USB Reset from Suspend State (1)



(8) USB reset from suspend state (2)

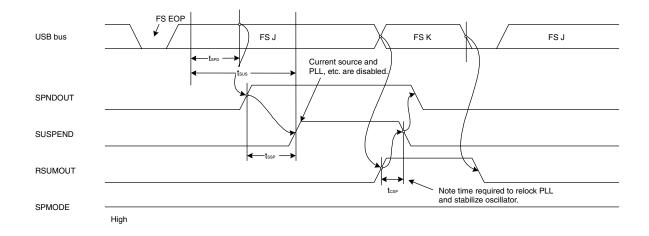
Figure 2-17. USB Reset from Suspend State (2)





(9) Suspend and resume on USB1.1 bus

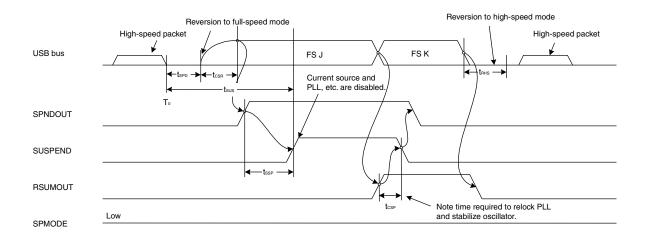
Figure 2-18. Suspend and Resume on USB 1.1 Bus





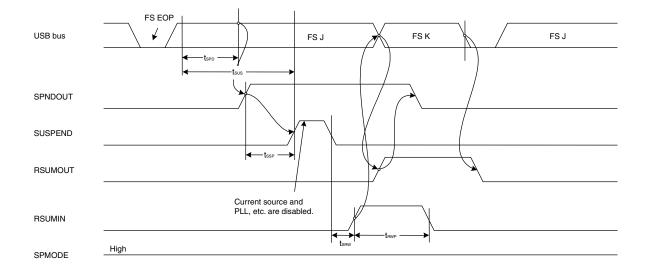
(10) Suspend and resume on USB2.0 bus

Figure 2-19. Suspend and Resume on USB 2.0 Bus



(11) Remote wakeup on USB1.1

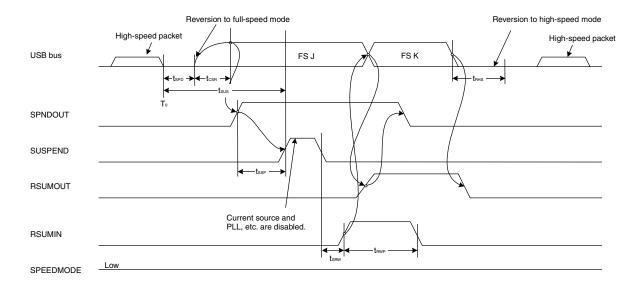
Figure 2-20. Remote Wakeup on USB 1.1





(12) Remote wakeup on USB2.0

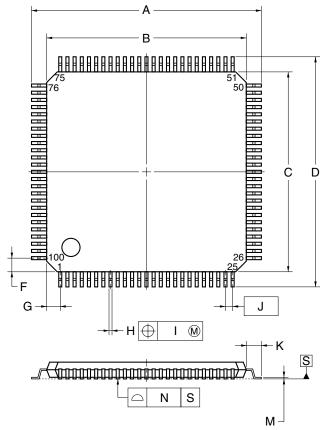
Figure 2-21. Remote Wakeup on USB 2.0



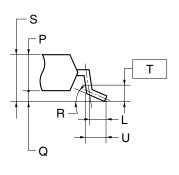


3. PACKAGE DRAWING

* 100-PIN PLASTIC TQFP (FINE PITCH) (14x14)



detail of lead end



NOTE

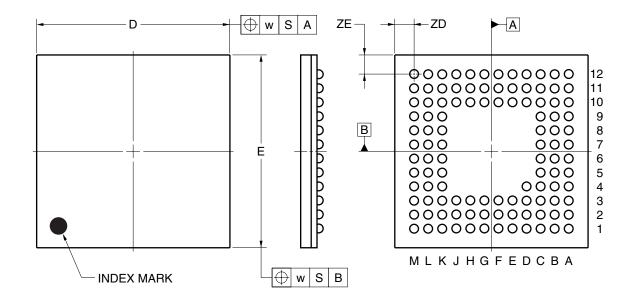
Each lead centerline is located within 0.08 mm of its true position (T.P.) at maximum material condition.

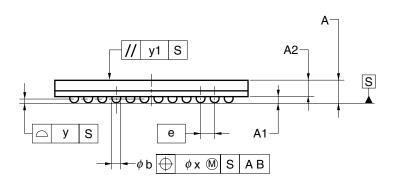
ITEM	MILLIMETERS
Α	16.0±0.2
В	14.0±0.2
С	14.0±0.2
D	16.0±0.2
F	1.0
G	1.0
Н	0.22±0.05
ı	0.08
J	0.5 (T.P.)
K	1.0±0.2
L	0.5
М	$0.17^{+0.03}_{-0.07}$
N	0.08
Р	1.0
Q	0.1±0.05
R	3°+4° -3°
S	1.1±0.1
Т	0.25
U	0.6±0.15
	D40000 F0 0FU

P100GC-50-9EU



109-PIN PLASTIC FBGA (11x11)





	(UNIT:mm)
ITEM	DIMENSIONS
D	11.00±0.10
E	11.00±0.10
w	0.20
Α	1.28±0.10
Α1	0.35±0.06
A2	0.93
е	0.80
b	$0.50^{+0.05}_{-0.10}$
х	0.08
у	0.10
y1	0.20
ZD	1.10
ZE	1.10
	P109F1-80-DN2



4. RECOMMENDED SOLDERING CONDITIONS

The μ PD720122 should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, contact your NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

• μ PD720122GC-9EU : 100-pin plastic TQFP (Fine pitch) (14 × 14)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher),	IR35-103-2
	Count: Two times or less	
	Exposure limit: 3 days ^{Note} (after that, prebake at 125°C for 10 hours)	
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	_

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

• μ PD720122F1-GN2 : 109-pin plastic FBGA (11 \times 11)

Soldering Method	Soldering Conditions	Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher),	IR35-103-3
	Count: Three times or less	
	Exposure limit: 3 days ^{Note} (after that, prebake at 125°C for 10 hours)	
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	_

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

[MEMO]



NOTES FOR CMOS DEVICES —

(1) PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.



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